SSD1306

Advance Information

128 x 64 Dot Matrix **OLED/PLED Segment/Common Driver with Controller**

This document contains information on a new product. Specifications and information herein are subject to change without notice.



Appendix: IC Revision history of SSD1306 Specification

Version	Change Items	Effective Date
1.0	1 st release	3-Oct-07
1.1	1. Revise typo	29-Apr-08
	2. Revise command table	
1.2	Add Charge pump section	07-Jul-09
	2. Add Advance graphic commands : 23h, D6h	
1.3	1. Revise Section 8.10 Charge Pump Regulator	07-May-10
	2. Revise Section 12 DC Characteristics	
	3. Revise min. t _{AS} Address Setup Time in Table 13-2 to 5ns	
	4. Add Figure 10-7 Oscillator frequency setting	
	5. Update declaimer	
1.4	 Replace SSD1306Z by SSD1306Z2 and add SSD1306Z2 into ordering information (P.7) 	13-Jul-10
	 Add Power ON and OFF sequence with Charge Pump Application in section 8.9 (p.29) 	
1.5	 Update Power on/off sequence with charge pump application in section 8.9 (p.29) 	27-Aug-10

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1 GENERAL DESCRIPTION

SSD1306 is a single-chip CMOS OLED/PLED driver with controller for organic / polymer light emitting diode dot-matrix graphic display system. It consists of 128 segments and 64 commons. This IC is designed for Common Cathode type OLED panel.

The SSD1306 embeds with contrast control, display RAM and oscillator, which reduces the number of external components and power consumption. It has 256-step brightness control. Data/Commands are sent from general MCU through the hardware selectable 6800/8000 series compatible Parallel Interface, I²C interface or Serial Peripheral Interface. It is suitable for many compact portable applications, such as mobile phone sub-display, MP3 player and calculator, etc.

2 FEATURES

- Resolution: 128 x 64 dot matrix panel
- Power supply
 - o $V_{DD} = 1.65 \text{V to } 3.3 \text{V}, < V_{BAT}$ for IC logic
 - o $V_{BAT} = 3.3V$ to 4.2V for charge pump regulator circuit
 - o $V_{CC} = 7V$ to 15V for Panel driving
- For matrix display
 - o Segment maximum source current: 100uA
 - o Common maximum sink current: 15mA
 - o 256 step contrast brightness current control
- Embedded 128 x 64 bit SRAM display buffer
- Pin selectable MCU Interfaces:
 - o 8-bit 6800/8080-series parallel interface
 - o 3 /4 wire Serial Peripheral Interface
 - o I²C Interface
- Screen saving continuous scrolling function in both horizontal and vertical direction
- Internal charge pump regulator
- RAM write synchronization signal
- Programmable Frame Rate and Multiplexing Ratio
- Row Re-mapping and Column Re-mapping
- On-Chip Oscillator
- Chip layout for COG & COF
- Wide range of operating temperature: -40°C to 85°C

3 ORDERING INFORMATION

Table 3-1: Ordering Information

Ordering Part Number SE		COM	COM Package Form Reference		Remark	
SSD1306Z2	128	64	COG	9	 Min SEG pad pitch: 47um Min COM pad pitch: 40um Die thickness: 300 +/- 25um 	
SSD1306TR1	104	48	TAB	12, 61	 35mm film, 4 sprocket hole, Folding TAB 8-bit 80 / 8-bit 68 / SPI / I²C interface SEG, COM lead pitch 0.1mm x 0.997 =0.0997mm Die thickness: 457 +/- 25um 	

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4 BLOCK DIAGRAM

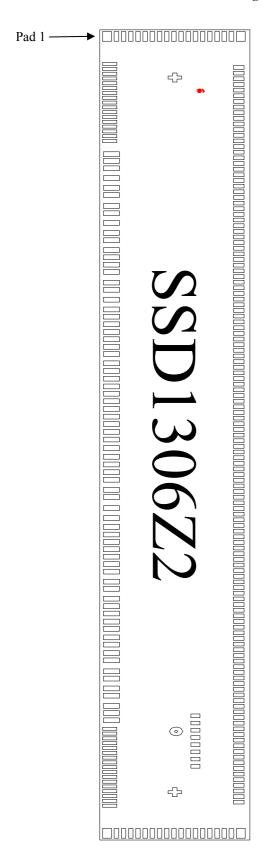
RES# CS# D/C# E (RD#) R/W#(WR#) Graphic Display Data RAM (GDDRAM) BS2 BS1 BS0 Display Controller Common Driver COM62 COM60 MCU Interface COM2 COM₀ SEG0 SEG1 Segment Driver SEG126 SEG127 V_{DD} COM1 ${\stackrel{V}{v}_{_{LSS}}}$ Common Driver COM3 Voltage Control Charge pump Regulator COM61 COM63 Current Control Command Decoder Oscillator V_{COMH} ← I_{REF} CL – CLS – BGGND – CON CONTRACTOR CONTRAC

Figure 4-1 SSD1306 Block Diagram

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DIE PAD FLOOR PLAN 5

Figure 5-1: SSD1306Z2 Die Drawing



D. C. (0	6.76
Die Size (after	6.76mm +/- 0.05mm x
sawing)	0.86mm +/- 0.05mm
Die thickness	300 +/- 15um
Min I/O pad pitch	60um
Min SEG pad pitch	47um
Min COM pad pitch	40um
Bump height	Nominal 12um

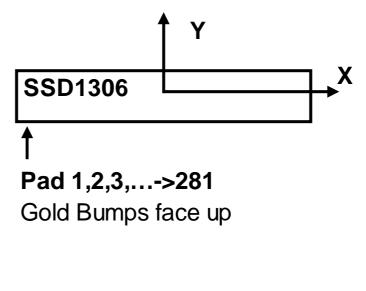
Bump size	
Pad 1, 106, 124, 256	80um x 50um
Pad 2-18, 89-105, 107-123, 257-273	25um x 80um
Pad 19-88	40um x 89um
Pad 125-255	31um x 59um
Pad 274-281 (TR pads)	30um x 50um

Alignment mark	Position	Size	
+ shape	(-2973, 0)	75um x 75um	
+ shape	(2973, 0)	75um x 75um	
Circle	(2466.665, 7.575)	R37.5um, inner 18um	
SSL Logo	(-2862.35, 144.82)	-	

(For details dimension please see p.9)

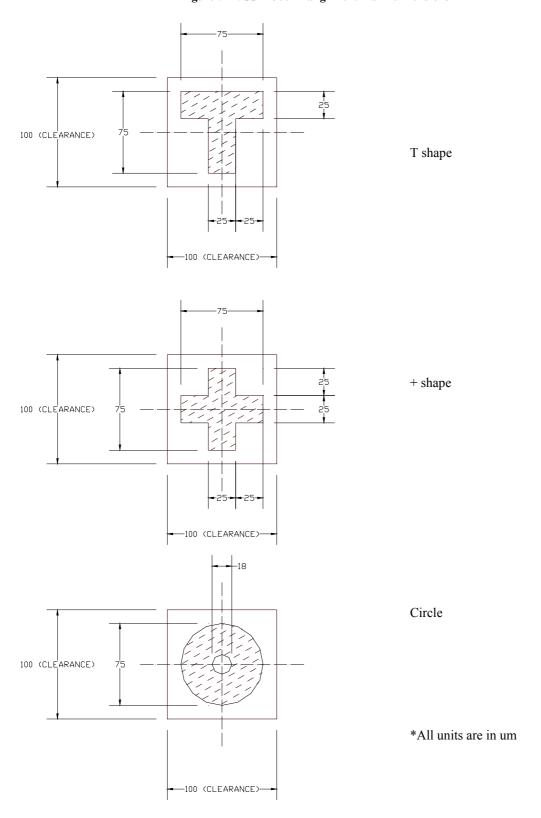
Note

- (1) Diagram showing the Gold bumps face up.
- (2) Coordinates are referenced to center of the chip.
- (3) Coordinate units and size of all alignment marks are in um.
 (4) All alignment keys do not contain gold



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Figure 5-2: SSD1306Z2 alignment mark dimensions



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Table 5-1: SSD1306Z2 Bump Die Pad Coordinates

Pad no.	Pad Name NC	-3315	Y-pos -377.5
2	VSS	-3084.77	-362.5
3	COM49	-3044.77	-362.5
4	COM50	-3004.77	-362.5
5	COM51	-2964.77	-362.5
6	COM52	-2924.77	-362.5
7	COM53	-2884.77	-362.5
8	COM54	-2844.77	-362.5
9	COM55	-2804.77	-362.5
10	COM56	-2764.77	-362.5
11	COM57	-2724.77	-362.5
12	COM58	-2684.77 -2644.77	-362.5
13	COM59		-362.5
15	COM60 COM61	-2604.77 -2564.77	-362.5 -362.5
16	COM62	-2524.77	-362.5
17	COM63	-2324.77	-362.5
18	VCOMH	-2444.77	-362.5
19	NC	-2334.965	-352.83
20	C2P	-2278.265	-352.83
21	C2P	-2218.265	-352.83
22	C2N	-2136.715	-352.83
23	C2N	-2055.465	-352.83
24	C1P	-1995.465	-352.83
25	C1P	-1904.115	-352.83
26	CIN	-1844.115	-352.83
27	CIN	-1762.865	-352.83
28	VBAT	-1679.31	-352.83
29	VBAT	-1619.31	-352.83
30	VBREF	-1537.51	-352.83
31	BGGND	-1477.51	-352.83
32	VCC	-1416.01	-352.83
33	VCC	-1356.01	-352.83
34	VCOMH	-1266.955	-352.83
35	VCOMH	-1206.955	-352.83
36	VLSS	-1125.155	-352.83
37	VLSS	-1043.355	-352.83
38	VLSS	-983.355	-352.83
39	VSS	-920	-352.83
40	VSS	-856	-352.83
41	VSS	-796	-352.83
42	VDD	-732.645	-352.83
43	VDD	-672.645	-352.83
44	BS0	-595.655	-352.83
45	VSS	-531.955	-352.83
46	BS1	-467.655	-352.83
47	VDD	-403.155	-352.83
48	VDD	-342.555	-352.83
49	BS2	-279.705	-352.83
50	VSS	-215.705 -151.955	-352.83
51	FR	-89.815	-352.83
52	CL		-352.83
53 54	VSS CS#	-25.665 38.635	-352.83 -352.83
55	RES#	109.835	-352.83
56	D/C#	182.425	-352.83
57	VSS	246.125	-352.83
58	R/W#	310.425	-352.83
59	E	373.125	-352.83
60	VDD	457.175	-352.83
61	VDD	517.175	-352.83
62	D0	609.275	-352.83
63	D1	692.475	-352.83
64	D2	765.675	-352.83
65	D3	828.875	-352.83
66	VSS	890.325	-352.83
67	D4	951.275	-352.83
68	D5	1013.315	-352.83
69	D6	1075.355	-352.83
70	D7	1137.395	-352.83
71	VSS	1220.735	-352.83
72	VSS	1280.735	-352.83
73	CLS	1362.585	-352.83
74	VDD	1425.285	-352.83
75	VDD	1485.885	-352.83
76	VDD	1553.185	-352.83
77	VDD	1613.185	-352.83
	IREF	1684.585	-352.83
78 79	IREF	1744.585	-352.83

	able 5-1	: SSD13	06Z2 I
Pad no.	Pad Name	X-pos	Y-pos
81	VCOMH	1875.585	-352.83
82 83	VCC VCC	1967.185 2027.185	-352.83 -352.83
	VLSS		
84		2109.185	-352.83 -352.83
85	VLSS	2169.185	
86	VLSS	2254.185	-352.83
87 88	NC NC	2314.185 2374.185	-352.83 -352.83
89		2444.77	
90	VSS COM31	2484.77	-362.5 -362.5
91	COM30	2524.77	
92		2564.77	-362.5 -362.5
92	COM29		
93	COM28 COM27	2604.77 2644.77	-362.5 -362.5
95	COM26	2684.77	-362.5
96	COM25	2724.77	-362.5
97	COM24	2764.77	-362.5
98	COM23	2804.77	-362.5
99	COM22	2844.77	-362.5
100	COM22 COM21	2884.77	-362.5
100	COM21		
101	COM20	2924.77 2964.77	-362.5
			-362.5
103 104	COM18 COM17	3004.77 3044.77	-362.5 -362.5
104	VSS	3084.77	
			-362.5
106	NC COM16	3315 3315	-377.5
107	COM16		-325
108	COM15	3315	-285
109 110	COM14 COM13	3315 3315	-245 -205
111	COM12	3315	-165
112	COM11	3315	-125
113	COM10	3315	-85
114	COM9	3315	-45
115	COM8	3315	-5 25
116	COM7	3315	35
117	COM6	3315	75
118	COM5	3315	115
119	COM4	3315	155
120	COM3	3315	195
121	COM2	3315	235
122	COM1	3315	275
123	COM0	3315	315
124	NC	3315	367.5
125	NC	3055.5	356
126	SEG0	3009.5	356
127	SEG1	2962.5	356
128	SEG2	2915.5	356
129	SEG3	2868.5	356
130	SEG4	2821.5	356
131	SEG5	2774.5	356
132	SEG6	2727.5	356
133	SEG7	2680.5	356
134	SEG8	2633.5	356
135	SEG9	2586.5	356
136	SEG10	2539.5	356
137	SEG11	2492.5	356
138	SEG12	2445.5	356
139	SEG13	2398.5	356
140	SEG14	2351.5	356
141	SEG15	2304.5	356
142	SEG16	2257.5	356
143	SEG17	2210.5	356
144	SEG18	2163.5	356
145	SEG19	2116.5	356
146	SEG20	2069.5	356
147	SEG21	2022.5	356
148	SEG22	1975.5	356
149	SEG23	1928.5	356
150	SEG24	1881.5	356
151	SEG25	1834.5	356
152	SEG26	1787.5	356
153	SEG27	1740.5	356
154	SEG28	1693.5	356
155	SEG29	1646.5	356
156	SEG30	1599.5	356
157	SEG31	1552.5	356
158	SEG32	1505.5	356
	SEG33	1458.5	356
159 160	SEG34	1411.5	356

Pad no.	Pad Name	X-pos	Y-pos
161 162	SEG35 SEG36	1364.5 1317.5	356 356
163	SEG37	1270.5	356
164	SEG38	1223.5	356
165 166	SEG39 SEG40	1176.5 1129.5	356 356
167	SEG40 SEG41	1082.5	356
168	SEG42	1035.5	356
169	SEG43	988.5	356
170	SEG44 SEG45	941.5	356
171 172	SEG45 SEG46	894.5 847.5	356 356
173	SEG47	800.5	356
174	SEG48	753.5	356
175 176	SEG49 SEG50	706.5 659.5	356 356
177	SEG50	612.5	356
178	SEG52	565.5	356
179	SEG53	518.5	356
180 181	SEG54 SEG55	471.5 424.5	356 356
182	SEG56	377.5	356
183	SEG57	330.5	356
184 185	SEG58 SEG59	283.5 236.5	356 356
186	SEG60	189.5	356
187	SEG61	142.5	356
188	SEG62	95.5	356
189 190	SEG63 SEG64	48.5 1.5	356 356
191	SEG65	-45.5	356
192	SEG66	-92.5	356
193	SEG67	-139.5	356
194 195	SEG68 SEG69	-186.5 -233.5	356 356
196	SEG70	-280.5	356
197	SEG71	-327.5	356
198 199	SEG72 SEG73	-374.5 -421.5	356 356
200	SEG73	-468.5	356
201	SEG75	-515.5	356
202	SEG76	-562.5	356
203	SEG77 SEG78	-609.5 -656.5	356 356
205	SEG79	-703.5	356
206	SEG80	-750.5	356
207 208	SEG81 SEG82	-797.5 -844.5	356 356
209	SEG82 SEG83	-891.5	356
210	NC	-940	356
211	SEG84	-988.5	356
212 213	SEG85 SEG86	-1035.5 -1082.5	356 356
214	SEG87	-1129.5	356
215	SEG88	-1176.5	356
216 217	SEG89 SEG90	-1223.5 -1270.5	356 356
217	SEG90 SEG91	-12/0.5	356
219	SEG92	-1364.5	356
220	SEG93	-1411.5	356
221	SEG94 SEG95	-1458.5 -1505.5	356 356
223	SEG96	-1552.5	356
224	SEG97	-1599.5	356
225 226	SEG98 SEG99	-1646.5 -1693.5	356 356
227	SEG100	-1093.5	356
228	SEG101	-1787.5	356
229	SEG102	-1834.5	356
230 231	SEG103 SEG104	-1881.5 -1928.5	356 356
232	SEG104 SEG105	-1928.5	356
233	SEG106	-2022.5	356
234 235	SEG107	-2069.5	356
236	SEG108 SEG109	-2116.5 -2163.5	356 356
237	SEG110	-2210.5	356
238	SEG111	-2257.5	356
239	SEG112 SEG113	-2304.5 -2351.5	356 356
240	01103	-2331.3	220

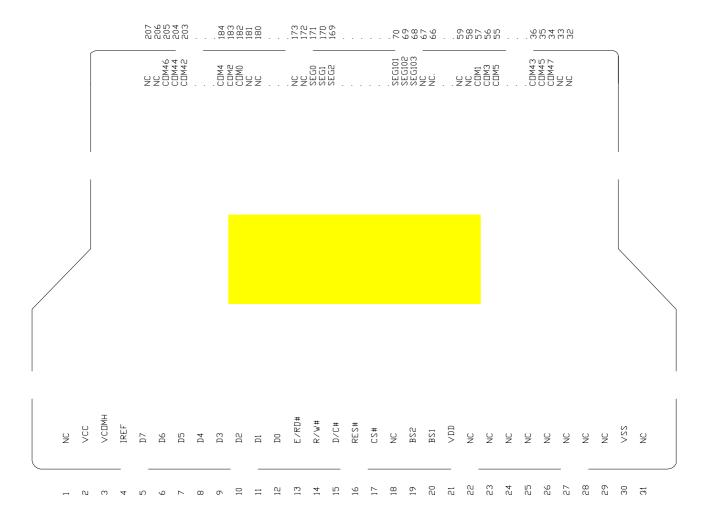
Pad no.	Pad Name	X-pos	Y-pos
241	SEG114	-2398.5	356
242	SEG115	-2445.5	356
243	SEG116	-2492.5	356
244	SEG117	-2539.5	356
245	SEG118	-2586.5	356
246	SEGI19	-2633.5	356
247	SEG120	-2680.5	356
248	SEG121	-2727.5	356
249	SEG121	-2774.5	356
250	SEG123	-2821.5	356
251	SEG124	-2868.5	356
252	SEG125	-2915.5	356
253	SEG126	-2962.5	356
254	SEG120	-3009.5	356
255	NC	-3056.5	356
256	NC	-3315	367.5
257	COM32	-3315	315
258	COM33	-3315	275
259	COM34	-3315	235
260	COM35	-3315	195
261	COM36	-3315	155
262	COM37	-3315	115
263	COM38	-3315	75
264	COM39	-3315	35
265	COM40	-3315	-5
266	COM41	-3315	-45
267	COM42	-3315	-85
268	COM43	-3315	-125
269	COM44	-3315	-165
270	COM45	-3315	-205
271	COM46	-3315	-245
272	COM47	-3315	-245
273	COM48	-3315	-325
213	COMT-0	-3313	-323
Pad no.	Pad Name	X-pos	Y-pos
Pin#	Pin name	X-pos X-dir	Y-dir
274	TR0	2757.05	114.8
275	TR1	2697.05	114.8
276	TR2	2637.05	114.8
277	TR3	2577.05	114.8
278	VSS	2517.05	114.8
279	TR4	2457.05	114.8
280	TR5	2397.05	114.8
281	TR6	2337.05	114.8
201	110	2331.03	117.0

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PIN ARRANGEMENT

SSD1306TR1 pin assignment 6.1

Figure 6-1: SSD1306TR1 Pin Assignment



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Note: (1) COM sequence (Split) is under command setting: DAh, 12h

Table 6-1 : SSD1306TR1 Pin Assignment Table

Table		
Pin no.	Pin Name	
1	NC	
2	VCC	
3	VCOMH	
4	IREF	
5	D7	
6	D6	
7	D5	
8	D4	
9	D3 D2	
10 11	D1	
12	D0	
13	E/RD#	
14	R/W#	
15	D/C#	
16	RES#	
17	CS#	
18	NC	
19	BS2	
20	BS1	
21	VDD	
22	NC	
23	NC	l
24	NC	l
25	NC	l
26	NC	ĺ
27	NC	l
28	NC NO	ĺ
29	NC V/O	l
30	VSS	
31	NC NC	l
32	NC NO	
33	NC	
34	COM47	
35	COM45	
36	COM43	
37 38	COM41 COM39	
	COM37	
39 40	COM35	
41	COM33	
42	COM31	
43	COM29	
44	COM27	
45	COM25	
46	COM23	
47	COM21	
48	COM19	
49	COM17	
50	COM15	
51	COM13	
52	COM11	l
53	COM9	l
54	COM7	l
55	COM5	l
56	COM3	l
57	COM1	l
58	NC	l
59	NC	l
60	NC	l
61	NC NO	l
62	NC NO	ĺ
63	NC NC	ĺ
64	NC NC	ĺ
65	NC NC	ĺ
66	NC NC	ĺ
67	NC SEC103	ĺ
68	SEG103	l
69	SEG102	l
70	SEG101	l
71	SEG100	l
72	SEG99	l
73	SEG98	l
74	SEG97	l
75 76	SEG96	l
76 77	SEG95	ĺ
77	SEG94	ĺ
78 79	SEG93 SEG92	ĺ
80	SEG92 SEG91	l
50	02001	1

: SSD1306T	R1 Pin Assig
Pin no.	Pin Name
81	SEG90
82	SEG89
83	SEG88
84 85	SEG87 SEG86
86	SEG85
87	SEG84
88	SEG83
89	SEG82
90	SEG81
91	SEG80
92	SEG79
93	SEG78
94	SEG77
95	SEG76
96	SEG75
97 98	SEG74 SEG73
99	SEG73
100	SEG71
101	SEG70
102	SEG69
103	SEG68
104	SEG67
105	SEG66
106	SEG65
107	SEG64
108	SEG63
109	SEG62
110 111	SEG61 SEG60
111	SEG60 SEG59
112	SEG59 SEG58
114	SEG57
115	SEG56
116	SEG55
117	SEG54
118	SEG53
119	SEG52
120	SEG51
121	SEG50
122	SEG49
123	SEG48
124 125	SEG47 SEG46
125	SEG45
127	SEG44
128	SEG43
129	SEG42
130	SEG41
131	SEG40
132	SEG39
133	SEG38
134	SEG37
135	SEG36
136	SEG35
137	SEG34
138 139	SEG33 SEG32
139	SEG32 SEG31
141	SEG30
142	SEG29
143	SEG28
144	SEG27
145	SEG26
146	SEG25
147	SEG24
148	SEG23
149	SEG22
150	SEG21
151 152	SEG20 SEG19
152 153	SEG19 SEG18
153	SEG18 SEG17
155	SEG17
156	SEG15
157	SEG14
158	SEG13
159	SEG12
160	SEG11

Pin no.	Pin Name
161	SEG10
162	SEG9
163	SEG8
164	SEG7
165	SEG6
166	SEG5
167	SEG4
168	SEG3
169	SEG2
170	SEG1
171	SEG0
172	NC
173	NC
174	NC
175	NC
176	NC
177	NC
178	NC
179	NC
180	NC
181	NC
182	COM0
183	COM2
184	COM4
185	COM6
186	COM8
187	COM10
188	COM12
189	COM14
190	COM16
191	COM18
192	COM20
193	COM22
194	COM24
195	COM26
196	COM28
197	COM30
198	COM32
199	COM34
200	COM36
201	COM38
202	COM40
203	COM42
204	COM44
205	COM46
206	NC
207	NC NC

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7 PIN DESCRIPTION

Key:

I = Input	NC = Not Connected
O =Output	Pull LOW= connect to Ground
I/O = Bi-directional (input/output)	Pull HIGH= connect to V _{DD}
P = Power pin	

Figure 7-1 Pin Description

Pin Name	Type	Description							
V_{DD}	P	Power supply	Power supply pin for core logic operation.						
V _{CC}	P		Power supply for panel driving voltage. This is also the most positive power voltage supply pin. When charge pump is enabled, a capacitor should be connected between this pin and V_{SS} .						
V_{SS}	P	This is a grou	and pin.						
V _{LSS}	P	This is an ana	alog ground pin. It sl	nould be connected to	V_{SS} externally.				
V _{COMH}	О		COM signal deselected hould be connected	ed voltage level. between this pin and '	V_{SS} .				
V _{BAT}	P	Power supply	for charge pump re	gulator circuit.					
		Status Enable charge pump	V _{BAT} Connect to external V _{BAT} source	V_{DD} Connect to external V_{DD} source	$V_{\rm CC}$ A capacitor should be connected between this pin and $V_{\rm SS}$				
		Disable charge pump	Keep float	Connect to external V _{DD} source	Connect to external V _{CC} source				
BGGND	P		. It should be conne						
C1P/C1N C2P/C2N	I		C1P/C1N – Pin for charge pump capacitor; Connect to each other with a capacitor. C2P/C2N – Pin for charge pump capacitor; Connect to each other with a capacitor.						
V _{BREF}	P	Reserved pin	. It should be kept N	NC.					
BS[2:0]	I	MCU bus int	erface selection pins	. Please refer to Table	e 7-1 for the details of setting.				
I_{REF}	I	A resistor sh			$V_{\rm SS}$ to maintain the I _{REF} current at 12.5 lue.	uA.			
FR	О	and frame dis	This pin outputs RAM write synchronization signal. Proper timing between MCU data writing and frame display timing can be achieved to prevent tearing effect. It should be kept NC if it is not used. Please refer to Section 8.4 for details usage.						
CL	I	When international connected to	This is external clock input pin. When internal clock is enabled (i.e. HIGH in CLS pin), this pin is not used and should be connected to V_{SS} . When internal clock is disabled (i.e. LOW in CLS pin), this pin is the external clock source input pin.						
CLS	I	enabled. Who		, the internal clock is	GH (i.e. connect to V_{DD}), internal clo disabled; an external clock source mu				

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Pin Name	Type	Description
RES#	I	This pin is reset signal input. When the pin is pulled LOW, initialization of the chip is executed. Keep this pin HIGH (i.e. connect to $V_{\rm DD}$) during normal operation.
CS#	Ι	This pin is the chip select input. (active LOW).
D/C#	Ι	This is Data/Command control pin. When it is pulled HIGH (i.e. connect to V_{DD}), the data at D[7:0] is treated as data. When it is pulled LOW, the data at D[7:0] will be transferred to the command register. In I ² C mode, this pin acts as SA0 for slave address selection. When 3-wire serial interface is selected, this pin must be connected to V_{SS} . For detail relationship to MCU interface signals, please refer to the Timing Characteristics Diagrams: Figure 13-1 to Figure 13-5 .
E (RD#)	I	When interfacing to a 6800-series microprocessor, this pin will be used as the Enable (E) signal. Read/write operation is initiated when this pin is pulled HIGH (i.e. connect to $V_{\rm DD}$) and the chip is selected. When connecting to an 8080-series microprocessor, this pin receives the Read (RD#) signal. Read operation is initiated when this pin is pulled LOW and the chip is selected. When serial or I^2C interface is selected, this pin must be connected to $V_{\rm SS}$.
R/W#(WR#)	I	This is read / write control input pin connecting to the MCU interface. When interfacing to a 6800-series microprocessor, this pin will be used as Read/Write (R/W#) selection input. Read mode will be carried out when this pin is pulled HIGH (i.e. connect to $V_{\rm DD}$) and write mode when LOW. When 8080 interface mode is selected, this pin will be the Write (WR#) input. Data write operation is initiated when this pin is pulled LOW and the chip is selected. When serial or I^2C interface is selected, this pin must be connected to $V_{\rm SS}$.
D[7:0]	Ю	These are 8-bit bi-directional data bus to be connected to the microprocessor's data bus. When serial interface mode is selected, D0 will be the serial clock input: SCLK; D1 will be the serial data input: SDIN and D2 should be kept NC. When I²C mode is selected, D2, D1 should be tied together and serve as SDA _{out} , SDA _{in} in application and D0 is the serial clock input, SCL.
TR0-TR6	-	Testing reserved pins. It should be kept NC.
SEG0 ~ SEG127	О	These pins provide Segment switch signals to OLED panel. These pins are V_{SS} state when display is OFF.
COM0 ~ COM63	О	These pins provide Common switch signals to OLED panel. They are in high impedance state when display is OFF.
NC	-	This is dummy pin. Do not group or short NC pins together.

Table 7-1: MCU Bus Interface Pin Selection

SSD1306 Pin Name	I ² C Interface	6800-parallel interface (8 bit)	8080-parallel interface(8 bit)	4-wire Serial interface	3-wire Serial interface
BS0	0	0	0	0	1
BS1	1	0	1	0	0
BS2	0	1	1	0	0

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Note $$^{(1)}\,0$ is connected to V_{SS} $^{(2)}\,1$ is connected to V_{DD}

8 FUNCTIONAL BLOCK DESCRIPTIONS

8.1 MCU Interface selection

SSD1306 MCU interface consist of 8 data pins and 5 control pins. The pin assignment at different interface mode is summarized in Table 8-1. Different MCU mode can be set by hardware selection on BS[2:0] pins (please refer to Table 7-1 for BS[2:0] setting).

Table 8-1: MCU interface assignment under different bus interface mode

Pin Name	n Name Data/Command Interface						Contro	l Signal					
Bus													
Interface	D7	D6	D5	D4	D3	D2	D1	D 0	E	R/W#	CS#	D/C#	RES#
8-bit 8080				D	[7:0]				RD#	WR#	CS#	D/C#	RES#
8-bit 6800				D	[7:0]				Е	R/W#	CS#	D/C#	RES#
3-wire SPI	Tie LO	OW				NC	SDIN	SCLK	Tie LO	W	CS#	Tie LOW	RES#
4-wire SPI	Tie LO	OW				NC	SDIN	SCLK	Tie LO	W	CS#	D/C#	RES#
I ² C	Tie LO	OW				SDA _{OUT}	SDA_{IN}	SCL	Tie LO	W		SA0	RES#

8.1.1 MCU Parallel 6800-series Interface

The parallel interface consists of 8 bi-directional data pins (D[7:0]), R/W#, D/C#, E and CS#.

A LOW in R/W# indicates WRITE operation and HIGH in R/W# indicates READ operation. A LOW in D/C# indicates COMMAND read/write and HIGH in D/C# indicates DATA read/write. The E input serves as data latch signal while CS# is LOW. Data is latched at the falling edge of E signal.

Table 8-2: Control pins of 6800 interface

Function	E	R/W#	CS#	D/C#
Write command	\downarrow	L	L	L
Read status	\downarrow	Н	L	L
Write data	\downarrow	L	L	Н
Read data	\downarrow	Н	L	Н

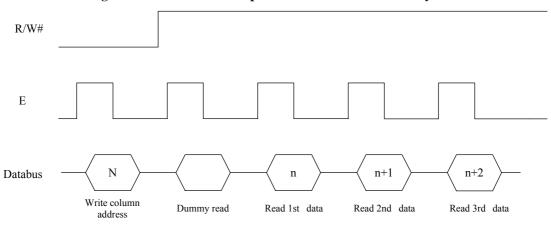
Note

(1) ↓ stands for falling edge of signal H stands for HIGH in signal L stands for LOW in signal

In order to match the operating frequency of display RAM with that of the microprocessor, some pipeline processing is internally performed which requires the insertion of a dummy read before the first actual display data read. This is shown in Figure 8-1.

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Figure 8-1: Data read back procedure - insertion of dummy read

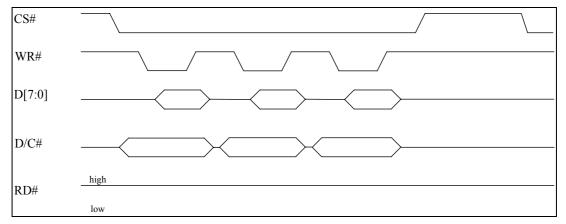


8.1.2 MCU Parallel 8080-series Interface

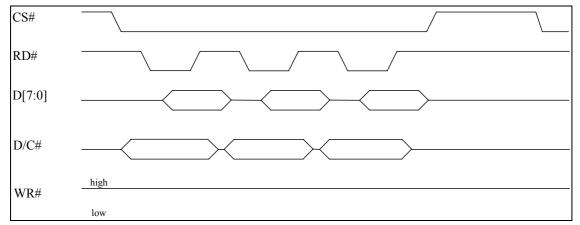
The parallel interface consists of 8 bi-directional data pins (D[7:0]), RD#, WR#, D/C# and CS#.

A LOW in D/C# indicates COMMAND read/write and HIGH in D/C# indicates DATA read/write. A rising edge of RD# input serves as a data READ latch signal while CS# is kept LOW. A rising edge of WR# input serves as a data/command WRITE latch signal while CS# is kept LOW.

Figure 8-2: Example of Write procedure in 8080 parallel interface mode



Figure~8-3: Example~of~Read~procedure~in~8080~parallel~interface~mode



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Table 8-3: Control pins of 8080 interface

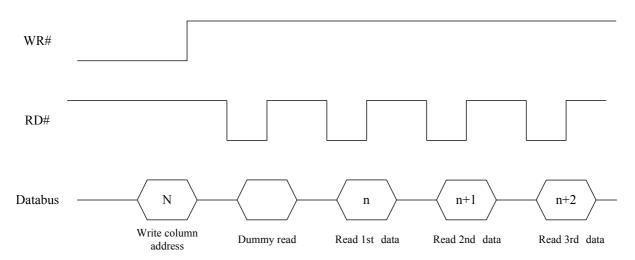
Function	RD#	WR#	CS#	D/C#
Write command	Н	↑	L	L
Read status	1	Н	L	L
Write data	Н	↑	L	Н
Read data	1	Н	L	Н

Note

- (1) ↑ stands for rising edge of signal
- (2) H stands for HIGH in signal
- (3) L stands for LOW in signal

In order to match the operating frequency of display RAM with that of the microprocessor, some pipeline processing is internally performed which requires the insertion of a dummy read before the first actual display data read. This is shown in Figure 8-4.

Figure 8-4: Display data read back procedure - insertion of dummy read



8.1.3 MCU Serial Interface (4-wire SPI)

The 4-wire serial interface consists of serial clock: SCLK, serial data: SDIN, D/C#, CS#. In 4-wire SPI mode, D0 acts as SCLK, D1 acts as SDIN. For the unused data pins, D2 should be left open. The pins from D3 to D7, E and R/W# (WR#)# can be connected to an external ground.

Table 8-4: Control pins of 4-wire Serial interface

Function	E(RD#)	R/W#(WR#)	CS#	D/C#	D 0
Write command	Tie LOW	Tie LOW	L	L	↑
Write data	Tie LOW	Tie LOW	L	Н	↑

Note

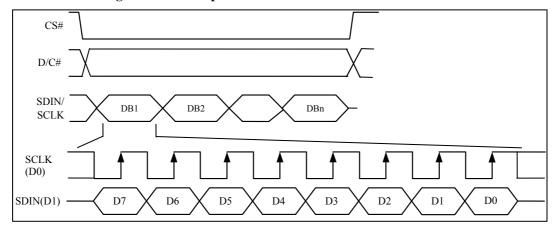
- (1) H stands for HIGH in signal
- (2) L stands for LOW in signal

SDIN is shifted into an 8-bit shift register on every rising edge of SCLK in the order of D7, D6, ... D0. D/C# is sampled on every eighth clock and the data byte in the shift register is written to the Graphic Display Data RAM (GDDRAM) or command register in the same clock.

Under serial mode, only write operations are allowed.

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Figure 8-5: Write procedure in 4-wire Serial interface mode



8.1.4 MCU Serial Interface (3-wire SPI)

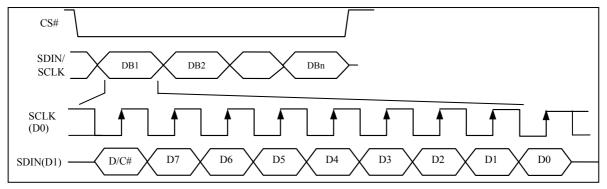
The 3-wire serial interface consists of serial clock SCLK, serial data SDIN and CS#. In 3-wire SPI mode, D0 acts as SCLK, D1 acts as SDIN. For the unused data pins, D2 should be left open. The pins from D3 to D7, R/W# (WR#)#, E and D/C# can be connected to an external ground.

The operation is similar to 4-wire serial interface while D/C# pin is not used. There are altogether 9-bits will be shifted into the shift register on every ninth clock in sequence: D/C# bit, D7 to D0 bit. The D/C# bit (first bit of the sequential data) will determine the following data byte in the shift register is written to the Display Data RAM (D/C# bit = 1) or the command register (D/C# bit = 0). Under serial mode, only write operations are allowed.

Table 8-5: Control pins of 3-wire Serial interface

Function	E(RD#)	R/W #(WR #)	CS#	D/C#	D 0	
Write command	Tie LOW	Tie LOW	L	Tie LOW	↑	Note
Write data	Tie LOW	Tie LOW	L	Tie LOW	1	(1) L stands for LOW in signal

Figure 8-6: Write procedure in 3-wire Serial interface mode



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8.1.5 MCU I²C Interface

The I^2C communication interface consists of slave address bit SA0, I^2C -bus data signal SDA (SDA_{OUT}/D₂ for output and SDA_{IN}/D₁ for input) and I^2C -bus clock signal SCL (D₀). Both the data and clock signals must be connected to pull-up resistors. RES# is used for the initialization of device.

a) Slave address bit (SA0)

SSD1306 has to recognize the slave address before transmitting or receiving any information by the I^2C -bus. The device will respond to the slave address following by the slave address bit ("SA0" bit) and the read/write select bit ("R/W#" bit) with the following byte format,

 $b_7 b_6 b_5 b_4 b_3 b_2 b_1 b_0$

0 1 1 1 1 0 SA0 R/W#

"SA0" bit provides an extension bit for the slave address. Either "0111100" or "0111101", can be selected as the slave address of SSD1306. D/C# pin acts as SA0 for slave address selection.

"R/W#" bit is used to determine the operation mode of the I^2C -bus interface. R/W#=1, it is in read mode. R/W#=0, it is in write mode.

b) I²C-bus data signal (SDA)

SDA acts as a communication channel between the transmitter and the receiver. The data and the acknowledgement are sent through the SDA.

It should be noticed that the ITO track resistance and the pulled-up resistance at "SDA" pin becomes a voltage potential divider. As a result, the acknowledgement would not be possible to attain a valid logic 0 level in "SDA".

"SDA_{IN}" and "SDA_{OUT}" are tied together and serve as SDA. The "SDA_{IN}" pin must be connected to act as SDA. The "SDA_{OUT}" pin may be disconnected. When "SDA_{OUT}" pin is disconnected, the acknowledgement signal will be ignored in the I^2 C-bus.

c) I²C-bus clock signal (SCL)

The transmission of information in the I²C-bus is following a clock signal, SCL. Each transmission of data bit is taken place during a single clock period of SCL.

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8.1.5.1 I^2 C-bus Write data

The I²C-bus interface gives access to write data and command into the device. Please refer to Figure 8-7 for the write mode of I²C-bus in chronological order.

Note: Co - Continuation bit D/C# - Data / Command Selection bit ACK - Acknowledgement SA0 - Slave address bit R/W# - Read / Write Selection bit $S-Start\ Condition\ /\ P-Stop\ Condition$ Write mode Slave Address 1 byte $n \ge 0$ bytes m > 0 words MSBLSB $\mathsf{I} \mathsf{I} \mathsf{I}$ SSD1306 Slave Address Control byte

Figure 8-7 : I²C-bus data format

8.1.5.2 Write mode for I^2C

- 1) The master device initiates the data communication by a start condition. The definition of the start condition is shown in Figure 8-8. The start condition is established by pulling the SDA from HIGH to LOW while the SCL stays HIGH.
- 2) The slave address is following the start condition for recognition use. For the SSD1306, the slave address is either "b0111100" or "b0111101" by changing the SA0 to LOW or HIGH (D/C pin acts as SA0)
- 3) The write mode is established by setting the R/W# bit to logic "0".
- 4) An acknowledgement signal will be generated after receiving one byte of data, including the slave address and the R/W# bit. Please refer to the Figure 8-9 for the graphical representation of the acknowledge signal. The acknowledge bit is defined as the SDA line is pulled down during the HIGH period of the acknowledgement related clock pulse.
- 5) After the transmission of the slave address, either the control byte or the data byte may be sent across the SDA. A control byte mainly consists of Co and D/C# bits following by six "0" 's.
 - a. If the Co bit is set as logic "0", the transmission of the following information will contain data bytes only.
 - b. The D/C# bit determines the next data byte is acted as a command or a data. If the D/C# bit is set to logic "0", it defines the following data byte as a command. If the D/C# bit is set to logic "1", it defines the following data byte as a data which will be stored at the GDDRAM. The GDDRAM column address pointer will be increased by one automatically after each data write.
- 6) Acknowledge bit will be generated after receiving each control byte or data byte.
- 7) The write mode will be finished when a stop condition is applied. The stop condition is also defined in Figure 8-8. The stop condition is established by pulling the "SDA in" from LOW to HIGH while the "SCL" stays HIGH.

Figure 8-8: Definition of the Start and Stop Condition

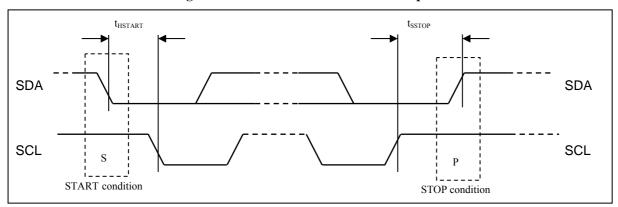
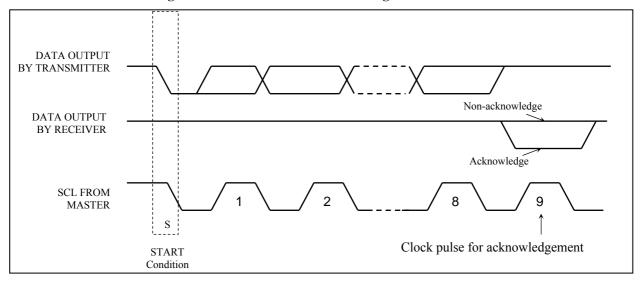


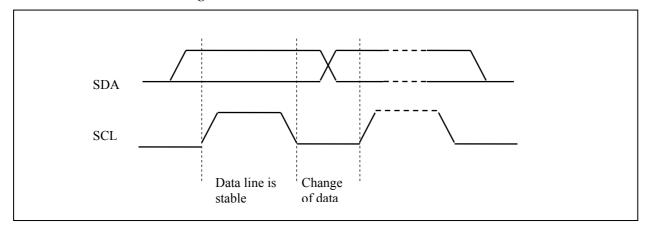
Figure 8-9: Definition of the acknowledgement condition



Please be noted that the transmission of the data bit has some limitations.

- 1. The data bit, which is transmitted during each SCL pulse, must keep at a stable state within the "HIGH" period of the clock pulse. Please refer to the Figure 8-10 for graphical representations. Except in start or stop conditions, the data line can be switched only when the SCL is LOW.
- 2. Both the data line (SDA) and the clock line (SCL) should be pulled up by external resistors.

Figure 8-10: Definition of the data transfer condition



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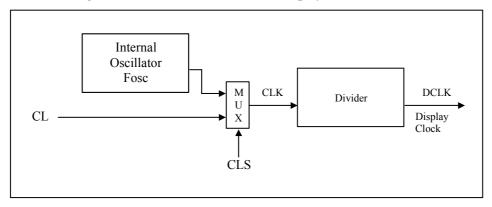
8.2 Command Decoder

This module determines whether the input data is interpreted as data or command. Data is interpreted based upon the input of the D/C# pin.

If D/C# pin is HIGH, D[7:0] is interpreted as display data written to Graphic Display Data RAM (GDDRAM). If it is LOW, the input at D[7:0] is interpreted as a command. Then data input will be decoded and written to the corresponding command register.

8.3 Oscillator Circuit and Display Time Generator

Figure 8-11: Oscillator Circuit and Display Time Generator



This module is an on-chip LOW power RC oscillator circuitry. The operation clock (CLK) can be generated either from internal oscillator or external source CL pin. This selection is done by CLS pin. If CLS pin is pulled HIGH, internal oscillator is chosen and CL should be connected to V_{SS} . Pulling CLS pin LOW disables internal oscillator and external clock must be connected to CL pins for proper operation. When the internal oscillator is selected, its output frequency Fosc can be changed by command D5h A[7:4].

The display clock (DCLK) for the Display Timing Generator is derived from CLK. The division factor "D" can be programmed from 1 to 16 by command D5h

$$DCLK = F_{OSC} / D$$

The frame frequency of display is determined by the following formula.

$$F_{FRM} = \frac{F_{osc}}{D \times K \times No. \text{ of Mux}}$$

where

- D stands for clock divide ratio. It is set by command D5h A[3:0]. The divide ratio has the range from 1 to
- K is the number of display clocks per row. The value is derived by

K = Phase 1 period + Phase 2 period + BANK0 pulse width

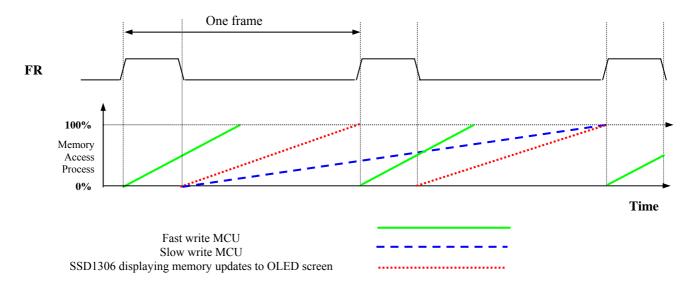
= 2 + 2 + 50 = 54 at power on reset

(Please refer to Section 8.6 "Segment Drivers / Common Drivers" for the details of the "Phase")

- Number of multiplex ratio is set by command A8h. The power on reset value is 63 (i.e. 64MUX).
- F_{OSC} is the oscillator frequency. It can be changed by command D5h A[7:4]. The higher the register setting results in higher frequency.

8.4 FR synchronization

FR synchronization signal can be used to prevent tearing effect.



The starting time to write a new image to OLED driver is depended on the MCU writing speed. If MCU can finish writing a frame image within one frame period, it is classified as fast write MCU. For MCU needs longer writing time to complete (more than one frame but within two frames), it is a slow write one.

For fast write MCU: MCU should start to write new frame of ram data just after rising edge of FR pulse and should be finished well before the rising edge of the next FR pulse.

For slow write MCU: MCU should start to write new frame ram data after the falling edge of the 1st FR pulse and must be finished before the rising edge of the 3rd FR pulse.

8.5 Reset Circuit

When RES# input is LOW, the chip is initialized with the following status:

- 1. Display is OFF
- 2. 128 x 64 Display Mode
- 3. Normal segment and display data column address and row address mapping (SEG0 mapped to address 00h and COM0 mapped to address 00h)
- 4. Shift register data clear in serial interface
- 5. Display start line is set at display RAM address 0
- 6. Column address counter is set at 0
- 7. Normal scan direction of the COM outputs
- 8. Contrast control register is set at 7Fh
- 9. Normal display mode (Equivalent to A4h command)

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8.6 Segment Drivers / Common Drivers

Segment drivers deliver 128 current sources to drive the OLED panel. The driving current can be adjusted from 0 to 100uA with 256 steps. Common drivers generate voltage-scanning pulses.

The segment driving waveform is divided into three phases:

- 1. In phase 1, the OLED pixel charges of previous image are discharged in order to prepare for next image content display.
- 2. In phase 2, the OLED pixel is driven to the targeted voltage. The pixel is driven to attain the corresponding voltage level from V_{SS} . The period of phase 2 can be programmed in length from 1 to 15 DCLKs. If the capacitance value of the pixel of OLED panel is larger, a longer period is required to charge up the capacitor to reach the desired voltage.
- 3. In phase 3, the OLED driver switches to use current source to drive the OLED pixels and this is the current drive stage.

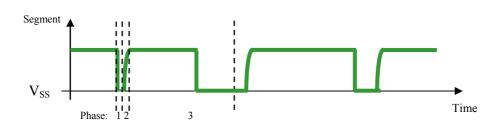


Figure 8-12 : Segment Output Waveform in three phases

After finishing phase 3, the driver IC will go back to phase 1 to display the next row image data. This three-step cycle is run continuously to refresh image display on OLED panel.

In phase 3, if the length of current drive pulse width is set to 50, after finishing 50 DCLKs in current drive phase, the driver IC will go back to phase 1 for next row display.

8.7 Graphic Display Data RAM (GDDRAM)

The GDDRAM is a bit mapped static RAM holding the bit pattern to be displayed. The size of the RAM is 128 x 64 bits and the RAM is divided into eight pages, from PAGE0 to PAGE7, which are used for monochrome 128x64 dot matrix display, as shown in Figure 8-13.

Row re-mapping PAGE0 (COM0-COM7) PAGE0 (COM 63-COM56) Page 0 PAGE1 (COM8-COM15) PAGE1 (COM 55-COM48) Page 1 PAGE2 (COM47-COM40) PAGE2 (COM16-COM23) Page 2 PAGE3 (COM24-COM31) PAGE3 (COM39-COM32) Page 3 PAGE4 (COM32-COM39) PAGE4 (COM31-COM24) Page 4 PAGE5 (COM40-COM47) PAGE5 (COM23-COM16) Page 5 PAGE6 (COM48-COM55) PAGE6 (COM15-COM8) Page 6 PAGE7 (COM56-COM63) PAGE7 (COM 7-COM0) Page 7 SEG0 -----SEG127 Column re-mapping

Figure 8-13: GDDRAM pages structure of SSD1306

When one data byte is written into GDDRAM, all the rows image data of the same page of the current column are filled (i.e. the whole column (8 bits) pointed by the column address pointer is filled.). Data bit D0 is written into the top row, while data bit D7 is written into bottom row as shown in Figure 8-14.

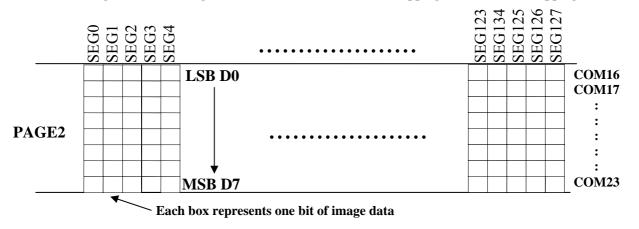


Figure 8-14: Enlargement of GDDRAM (No row re-mapping and column-remapping)

For mechanical flexibility, re-mapping on both Segment and Common outputs can be selected by software as shown in Figure 8-13.

For vertical shifting of the display, an internal register storing the display start line can be set to control the portion of the RAM data to be mapped to the display (command D3h).

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8.8 SEG/COM Driving block

This block is used to derive the incoming power sources into the different levels of internal use voltage and current.

- V_{CC} is the most positive voltage supply.
- V_{COMH} is the Common deselected level. It is internally regulated.
- V_{LSS} is the ground path of the analog and panel current.
- I_{REF} is a reference current source for segment current drivers I_{SEG}. The relationship between reference current and segment current of a color is:

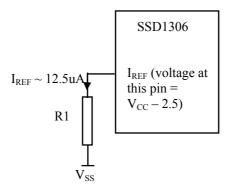
```
I_{SEG} = Contrast / 256 x I_{REF} x scale factor
```

in which

the contrast $(0\sim255)$ is set by Set Contrast command 81h; and the scale factor is 8 by default.

The magnitude of I_{REF} is controlled by the value of resistor, which is connected between I_{REF} pin and V_{SS} as shown in Figure 8-15. It is recommended to set I_{REF} to 12.5 \pm 2uA so as to achieve I_{SEG} = 100uA at maximum contrast 255.

Figure 8-15: I_{REF} Current Setting by Resistor Value



Since the voltage at I_{REF} pin is $V_{CC} - 2.5V$, the value of resistor R1 can be found as below:

For
$$I_{REF} = 12.5uA$$
, $V_{CC} = 12V$:

$$R1 = (Voltage at I_{REF} - V_{SS}) / I_{REF}$$

= $(12 - 2.5) / 12.5uA$
= $760K\Omega$

Power ON and OFF sequence

The following figures illustrate the recommended power ON and power OFF sequence of SSD1306:

Power ON and OFF sequence with External V_{CC} 8.9.1

Power ON sequence:

- 1. Power ON V_{DD}
- 2. After V_{DD} become stable, set RES# pin LOW (logic low) for at least 3us (t₁) (4) and then HIGH (logic
- 3. After set RES# pin LOW (logic low), wait for at least 3us (t₂). Then Power ON V_{CC.}⁽¹⁾
- 4. After V_{CC} become stable, send command AFh for display ON. SEG/COM will be ON after 100ms (t_{AF}).

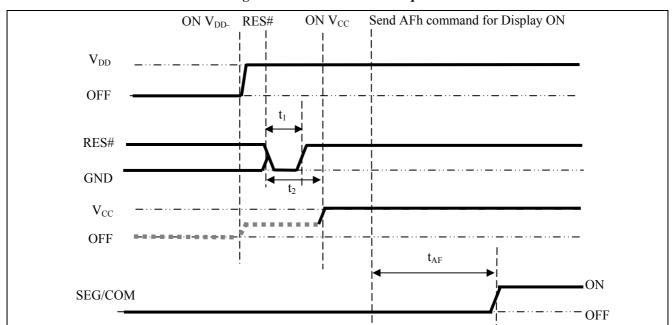


Figure 8-16: The Power ON sequence

Power OFF sequence:

- Send command AEh for display OFF.
 Power OFF V_{CC}. (1), (2), (3)
- 3. Power OFF V_{DD} after t_{OFF}. (5) (Typical t_{OFF}=100ms)

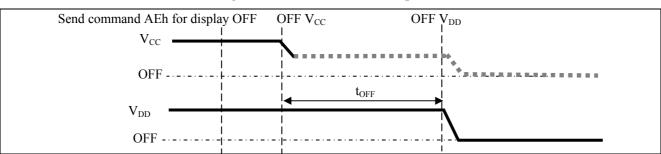


Figure 8-17: The Power OFF sequence

 $^{(1)}$ Since an ESD protection circuit is connected between V_{DD} and V_{CC} , V_{CC} becomes lower than V_{DD} whenever V_{DD} is ON and V_{CC} is OFF as shown in the dotted line of V_{CC} in Figure 8-16 and Figure 8-17.

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⁽²⁾V_{CC} should be kept float (i.e. disable) when it is OFF.

 $^{^{(3)}}$ Power Pins (V_{DD} , V_{CC}) can never be pulled to ground under any circumstance.

 $^{^{(4)}}$ The register values are reset after t_1 .

 $^{^{(5)}}$ V_{DD} should not be Power OFF before V_{CC} Power OFF.

8.9.2 Power ON and OFF sequence with Charge Pump Application

Power ON sequence:

- 1. Power ON V_{DD}
- Wait for t_{ON}. Power ON V_{BAT}. (1), (2) (where Minimum t_{ON} = 0ms)
 After V_{BAT} become stable, set RES# pin LOW (logic low) for at least 3us (t₁) (3) and then HIGH (logic
- 4. After set RES# pin LOW (logic low), wait for at least 3us (t₂). Then input commands with below sequence:
 - a. 8Dh 14h for enabling charge pump
 - b. AFh for display ON
- 5. SEG/COM will be ON after 100ms (t_{AF}).

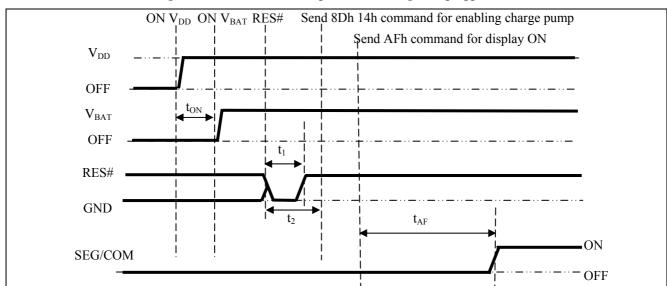


Figure 8-18: The Power ON sequence with Charge Pump Application

Power OFF sequence:

- 1. Send command AEh for display OFF
- Send command 8Dh 10h to disable charge pump
 Power OFF V_{BAT} after t_{OFF}. (1), (2) (Typical t_{OFF}=100ms)
- 4. Power OFF V_{DD} after t_{OFF2} . (where Minimum $t_{OFF2} = 0 \text{ms}^{(4)}$, Typical $t_{OFF2} = 5 \text{ms}$)

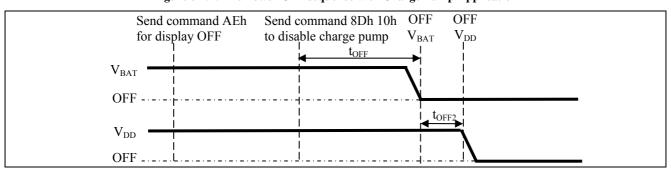


Figure 8-19: The Power OFF sequence with Charge Pump Application

 $^{(1)}V_{BAT}$ should be kept float (i.e. disable) when it is OFF.

 $^{(3)}$ The register values are reset after t_1 .

 $^{(4)}$ V_{DD} should not be Power OFF before V_{BAT} Power OFF

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Power Pins (V_{DD}, V_{BAT}) can never be pulled to ground under any circumstance.

8.10 Charge Pump Regulator

The internal regulator circuit in SSD1306 accompanying only 2 external capacitors can generate a 7.5V voltage supply, V_{CC} and a maximum output loading of 6mA, from a low voltage supply input, V_{BAT} . The V_{CC} is the voltage supply to the OLED driver block. This regulator can be turned ON/OFF by software command 8Dh setting.

9 COMMAND TABLE

Table 9-1: Command Table

(D/C#=0, R/W#(WR#) = 0, E(RD#=1) unless specific setting is stated)

	$D/C\pi$ 0,	1\(\frac{1}{2}\) \(\frac{1}{2}\) \(\frac{1}{2}\)	(W IXTT	<i>)</i> 0,	r(KD	_π 1) u	incss	specii	ic setti	iig is stateu)	
1. l	<u>Fundame</u>	ental (Comm	and T	Table						
$\mathbf{D}/0$	C# Hex	D7	D6	D5	D4	D3	D2	D1	D 0	Command	Description
0	81	1	0	0	0	0	0	0	1	Set Contrast Control	Double byte command to select 1 out of 256
0	A[7:0]	A_7	A_6	A_5	A_4	A_3	A_2	A_1	A_0		contrast steps. Contrast increases as the value
											increases.
											(RESET = 7Fh)
0	A4/A5	1	0	1	0	0	1	0	X_0	Entire Display ON	A4h, X ₀ =0b: Resume to RAM content display
											(RESET)
											Output follows RAM content
											A5h, X_0 =1b: Entire display ON
											Output ignores RAM content
0	A6/A7	1	0	1	0	0	1	1	X_0	Set Normal/Inverse	A6h, X[0]=0b: Normal display (RESET)
										Display	0 in RAM: OFF in display panel
											1 in RAM: ON in display panel
											A7h, X[0]=1b: Inverse display
											0 in RAM: ON in display panel
											1 in RAM: OFF in display panel
0	AΕ	1	0	1	0	1	1	1	X_0	Set Display ON/OFF	
	AF										(RESET)
											AFh X[0]=1b:Display ON in normal mode

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	rolling (Comi	mand	Tab							
D/C#	#Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0	26/27	0	0	1	0	0	1	1	X_0	Continuous	26h, X[0]=0, Right Horizontal Scroll
0	A[7:0]	0	0	0	0	0	0	0	0	Horizontal Scroll	27h, X[0]=1, Left Horizontal Scroll
0	B[2:0]	*	*	*	*	*	B_2	\mathbf{B}_1	B_0	Setup	(Horizontal scroll by 1 column)
0	C[2:0]	*	*	*	*	*	C_2	C_1	C_0		A[7:0]: Dummy byte (Set as 00h)
0	D[2:0]	*	*	*	*	*	$\overline{\mathrm{D}_2}$	D_1	D_0		B[2:0] : Define start page address
0	E[7:0]	0	0	0	0	0	0	0	0		000b – PAGE0 011b – PAGE3 110b – PAGE6
0	F[7:0]	1	1	1	1	1	1	1	1		001b - PAGE1 100b - PAGE4 111b - PAGE7
	' '										010b – PAGE2 101b – PAGE5
											C[2:0] : Set time interval between each scroll step in
											terms of frame frequency
											000b – 5 frames 100b – 3 frames
											001b – 64 frames 101b – 4 frames
											010b – 128 frames 110b – 25 frame
											011b – 256 frames 111b – 2 frame
											D[2:0] : Define end page address
											000b – PAGE0 011b – PAGE3 110b – PAGE6
											001b - PAGE1 100b - PAGE4 111b - PAGE7
											010b – PAGE2 101b – PAGE5
											The value of D[2:0] must be larger or equal
											to B[2:0]
											E[7:0] : Dummy byte (Set as 00h)
											F[7:0] : Dummy byte (Set as FFh)
0	29/2A	0	0	1	0	1	0	v	v	Continuous	29h, X ₁ X ₀ =01b : Vertical and Right Horizontal Scroll
0	A[2:0]	0	0	$\begin{vmatrix} 1 \\ 0 \end{vmatrix}$	0	1 0	$\begin{bmatrix} 0 \\ 0 \end{bmatrix}$	X_1	X_0	Vertical and	29h, X_1X_0 =010 · Vertical and Right Horizontal Scroll 2Ah, X_1X_0 =10b : Vertical and Left Horizontal Scroll
0	B[2:0]	*	*	*	*	*	-	\mathbf{B}_{1}	B_0	Horizontal Scroll	
0	C[2:0]	*	*	*	*	*	$egin{array}{c} B_2 \ C_2 \end{array}$	C_1	C_0	Setup	A[7:0]: Dummy byte
0	D[2:0]	*	*	*	*	*	D_2	D_1	D_0	Setup	ri[7.0]. Dunning Oyte
0	E[5:0]	*	*	E ₅	E ₄	E ₃	E_2	E_1	E_0		B[2:0] : Define start page address
U	E[3.0]	•		£5	E ₄	Е3	E-2	\mathbf{E}_1	E ₀		000b – PAGE0 011b – PAGE3 110b – PAGE6
											001b – PAGE1 100b – PAGE4 111b – PAGE7
											010b – PAGE2 101b – PAGE5
											C[2:0]: Set time interval between each scroll step in
											terms of frame frequency
											000b - 5 frames $100b - 3$ frames
											001b – 64 frames 101b – 4 frames
											010b – 128 frames 110b – 25 frame
											011b – 256 frames 111b – 2 frame
											D[2:0] : Define end page address
											000b – PAGE0 011b – PAGE3 110b – PAGE6
											001b – PAGE1 100b – PAGE4 111b – PAGE7
											010b – PAGE2 101b – PAGE5
											The value of D[2:0] must be larger or equal
											to B[2:0]
											' '
											E[5:0]: Vertical scrolling offset
											e.g. E[5:0]= 01h refer to offset =1 row
											E[5:0] = 3Fh refer to offset = 63 rows
											Note
											(1) No continuous vertical scrolling is available.

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2. Sci	olling	Comi	mand	Tab	le						
D/C #						D3	D2	D1	D0	Command	Description
	2E	0	0	1	0	1	1	1	0	Deactivate scroll	Stop scrolling that is configured by command 26h/27h/29h/2Ah. Note (1) After sending 2Eh command to deactivate the scrolling action, the ram data needs to be rewritten.
0	2F	0	0	1	0	1	1	1	1	Activate scroll	Start scrolling that is configured by the scrolling setup commands:26h/27h/29h/2Ah with the following valid sequences: Valid command sequence 1: 26h;2Fh. Valid command sequence 2: 27h;2Fh. Valid command sequence 3: 29h;2Fh. Valid command sequence 4: 2Ah;2Fh. For example, if "26h; 2Ah; 2Fh." commands are issued, the setting in the last scrolling setup command, i.e. 2Ah in this case, will be executed. In other words, setting in the last scrolling setup command overwrites the setting in the previous scrolling setup commands.
0	A3 A[5:0] B[6:0]	1 * *	0 * B ₆	1 A ₅ B ₅	0 A ₄ B ₄	0 A ₃ B ₃	0 A ₂ B ₂	1 A ₁ B ₁	1 A ₀ B ₀	Set Vertical Scrol	IA[5:0]: Set No. of rows in top fixed area. The No. of rows in top fixed area is referenced to the top of the GDDRAM (i.e. row 0).[RESET = 0] B[6:0]: Set No. of rows in scroll area. This is the number of rows to be used for vertical scrolling. The scroll area starts in the first row below the top fixed area. [RESET = 64] Note (1) A[5:0]+B[6:0] <= MUX ratio (2) B[6:0] <= MUX ratio (3a) Vertical scrolling offset (E[5:0] in 29h/2Ah) < B[6:0] (3b) Set Display Start Line (X ₅ X ₄ X ₃ X ₂ X ₁ X ₀ of 40h~7Fh) < B[6:0] (4) The last row of the scroll area shifts to the first row of the scroll area. (5) For 64d MUX display A[5:0] = 0, B[6:0]=64: whole area scrolls A[5:0] = 0, B[6:0] < 64: central area scrolls A[5:0] + B[6:0] < 64: bottom area scrolls

D/C #	Hex	D7	D6	D5	$\mathbf{D4}$	D3	D2	D1	$\mathbf{D0}$	Command	Description
1	00~0F	0	0	0	0	X_3	X_2	X_1	X_0	Set Lower Column	Set the lower nibble of the column start addres
										Start Address for	register for Page Addressing Mode using X[3:
										Page Addressing	as data bits. The initial display line register is
										Mode	reset to 0000b after RESET.
											Note
											(1) This command is only for page addressing mode

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3. A	ddressi	ng Set	tting (Comm	and T	Table					
D/C #	Hex	D7	D6	D 5	D4	D3	D2	D1	D 0	Command	Description
0	10~1F	0	0	0	1	X ₃	X ₂	X ₁	X_0	Set Higher Column Start Address for Page Addressing Mode	Set the higher nibble of the column start address register for Page Addressing Mode using X[3:0] as data bits. The initial display line register is reset to 0000b after RESET.
											(1) This command is only for page addressing mode
0	20	0	0	1	0	0	0	0	0	Set Memory	A[1:0] = 00b, Horizontal Addressing Mode
0	A[1:0]	*	*	*	*	*	*	A_1	A_0	Addressing Mode	A[1:0] = 01b, Vertical Addressing Mode A[1:0] = 10b, Page Addressing Mode (RESET) A[1:0] = 11b, Invalid
0	21	0	0	1	0	0	0	0	1	Set Column Address	Setup column start and end address
	A[6:0] B[6:0]	*	$egin{array}{c} A_6 \ B_6 \end{array}$	A ₅ B ₅	$egin{array}{c} A_4 \ B_4 \end{array}$	A ₃ B ₃	$egin{array}{c} A_2 \ B_2 \end{array}$	A_1 B_1	$egin{array}{c} A_0 \ B_0 \end{array}$		A[6:0] : Column start address, range : 0-127d, (RESET=0d)
											B[6:0]: Column end address, range : 0-127d, (RESET =127d) Note (1) This command is only for horizontal or vertical addressing mode.
0	22	0	0	1	0	0	0	1	0	Set Page Address	Setup page start and end address
	A[2:0]	*	*	*	*	*	A_2	\mathbf{A}_1	A_0		A[2:0]: Page start Address, range: 0-7d,
0	B[2:0]	*	*	*	*	*	B ₂	B ₁	B ₀		(RESET = 0d) B[2:0]: Page end Address, range: 0-7d, (RESET = 7d) Note (1) This command is only for horizontal or vertical addressing mode.
0	B0~B7	1	0	1	1	0	X_2	X_1	X_0	Set Page Start	Set GDDRAM Page Start Address
										Address for Page Addressing Mode	(PAGE0~PAGE7) for Page Addressing Mode using X[2:0].
											Note (1) This command is only for page addressing mode

4. Ha	rdware	Conf	igura	tion (l	Panel	resolu	ution	& lay	out rel	lated) Command Tab	le
D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D 0	Command	Description
0	40~7F	0	1	X ₅	X ₄	X ₃	X ₂	X ₁	X_0	Set Display Start Line	Set display RAM display start line register from 0-63 using $X_5X_3X_2X_1X_0$. Display start line register is reset to 000000b during RESET.
0	A0/A1	1	0	1	0	0	0	0	X_0	Set Segment Re-map	A0h, X[0]=0b: column address 0 is mapped to SEG0 (RESET) A1h, X[0]=1b: column address 127 is mapped to SEG0
0	A8	1	0	1	0	1	0	0	0	Set Multiplex Ratio	Set MUX ratio to N+1 MUX
0	A[5:0]	*	*	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀		N=A[5:0]: from 16MUX to 64MUX, RESET= 111111b (i.e. 63d, 64MUX) A[5:0] from 0 to 14 are invalid entry.

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4. Ha	rdware	Conf	igurat	tion (l	Panel	resolu	ution	& lay	out re	lated) Command Ta	ble
D/C #	Hex	D7	D6	D5	D4	D3	D2	D 1	D 0	Command	Description
0	C0/C8	1	1	0	0	X_3	0	0	0	Set COM Output	C0h, X[3]=0b: normal mode (RESET) Scan from
										Scan Direction	COM0 to COM[N –1]
											C8h, X[3]=1b: remapped mode. Scan from
											COM[N-1] to COM0
											Where N is the Multiplex ratio.
0	D3	1	1	0	1	0	0	1	1	Set Display Offset	Set vertical shift by COM from 0d~63d
0	A[5:0]	*	*	A_5	A_4	A_3	A_2	\mathbf{A}_1	A_0		The value is reset to 00h after RESET.
0	DA	1	1	0	1	1	0	1	0	Set COM Pins	A[4]=0b, Sequential COM pin configuration
0	A[5:4]	0	0	A_5	A_4	0	0	1	0	Hardware	A[4]=1b(RESET), Alternative COM pin
										Configuration	configuration
											A[5]=0b(RESET), Disable COM Left/Right
											remap
											A[5]=1b, Enable COM Left/Right remap

5. Ti	ming &	Drivi	ng Scl	heme	Settin	ng Cor	nmar	nd Tal	ble		
								D1		Command	Description
0	D5 A[7:0]	1 A ₇	1 A ₆	0 A ₅	1 A ₄	0 A ₃	1 A ₂	0 A ₁	1 A ₀	Set Display Clock Divide Ratio/Oscillator Frequency	A[3:0]: Define the divide ratio (D) of the display clocks (DCLK): Divide ratio= A[3:0] + 1, RESET is 0000b (divide ratio = 1) A[7:4]: Set the Oscillator Frequency, F _{OSC} . Oscillator Frequency increases with the value of A[7:4] and vice versa. RESET is 1000b Range:0000b~1111b Frequency increases as setting value increases.
0	D9 A[7:0]	1 A ₇	1 A ₆	0 A ₅	1 A ₄	1 A ₃	0 A ₂	0 A ₁	1 A ₀	Set Pre-charge Period	A[3:0]: Phase 1 period of up to 15 DCLK clocks 0 is invalid entry (RESET=2h) A[7:4]: Phase 2 period of up to 15 DCLK clocks 0 is invalid entry (RESET=2h)
0	DB A[6:4]	1 0	1 A ₆	0 A ₅	1 A ₄	1 0	0	1 0	1 0	Set V _{COMH} Deselect Level	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$
0	E3	1	1	1	0	0	0	1	1	NOP	Command for no operation

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6. A d	vance (Grap	hic C	omm	and '	Table					
D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0 0	A[6:0]	0 *	0 *	1 A5	0 A4	0 A3	0 A2	1 A1	1	Set Fade Out and Blinking	A[5:4] = 00b Disable Fade Out / Blinking Mode[RESET] A[5:4] = 10b Enable Fade Out mode. Once Fade Mode is enabled, contrast decrease gradually to all pixels OFF. Output follows RAM content when Fade mode is disabled. A[5:4] = 11b Enable Blinking mode. Once Blinking Mode is enabled, contrast decrease gradually to all pixels OFF and than contrast increase gradually to normal display. This process loop continuously until the Blinking mode is disabled. A[3:0] : Set time interval for each fade step A[3:0] Time interval for each fade step 0000b 8 Frames 0001b 16 Frames 0010b 24 Frames 1111b 128 Frames
											(1) Refer to section 10.3.1 for details.
0	D6 A[0]	1 0	1 0	0 0	1 0	0 0	1 0	1 0	0 A0	Set Zoom In	A[0] = 0b Disable Zoom in Mode[RESET] A[0] = 1b Enable Zoom in Mode Note (1) The panel must be in alternative COM pin configuration (command DAh A[4] =1) (2) Refer to section 10.3.2 for details.

7. Cha	rge Pur	np (Comm	and	Table	•					
D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
	8D	1	0	0	0	1	1	0	1	Charge	A[2] = 0b, Disable charge pump(RESET)
	A[7:0]	*	*	0	1	0	A_2	0	0	Pump	A[2] = 1b, Enable charge pump during display on
										Setting	
											Note
											(1) The Charge Pump must be enabled by the following
											command sequence:
											8Dh; Charge Pump Setting
											14h; Enable Charge Pump
											AFh; Display ON

Note
(1) "*" stands for "Don't care".

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Table 9-2: Read Command Table

Bit Pattern	Command	Descrip	otion
$D_7D_6D_5D_4D_3D_2D_1D_0$	Status Register Read	D[7]:	Reserved
		D[6]:	"1" for display OFF / "0" for display ON
		D[5]:	Reserved
		D[4]:	Reserved
		D[3]:	Reserved
		D[2]:	Reserved
		D[1]:	Reserved
		D[0]:	Reserved

Note

9.1 Data Read / Write

To read data from the GDDRAM, select HIGH for both the R/W# (WR#) pin and the D/C# pin for 6800-series parallel mode and select LOW for the E (RD#) pin and HIGH for the D/C# pin for 8080-series parallel mode. No data read is provided in serial mode operation.

In normal data read mode the GDDRAM column address pointer will be increased automatically by one after each data read.

Also, a dummy read is required before the first data read.

To write data to the GDDRAM, select LOW for the R/W# (WR#) pin and HIGH for the D/C# pin for both 6800-series parallel mode and 8080-series parallel mode. The serial interface mode is always in write mode. The GDDRAM column address pointer will be increased automatically by one after each data write.

Table 9-3: Address increment table (Automatic)

D/C#	R/W# (WR#)	Comment	Address Increment
0	0	Write Command	No
0	1	Read Status	No
1	0	Write Data	Yes
1	1	Read Data	Yes

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⁽¹⁾ Patterns other than those given in the Command Table are prohibited to enter the chip as a command; as unexpected results can occur.

10 COMMAND DESCRIPTIONS

10.1 Fundamental Command

10.1.1 Set Lower Column Start Address for Page Addressing Mode (00h~0Fh)

This command specifies the lower nibble of the 8-bit column start address for the display data RAM under Page Addressing Mode. The column address will be incremented by each data access. Please refer to Section Table 9-1 and Section 10.1.3 for details.

10.1.2 Set Higher Column Start Address for Page Addressing Mode (10h~1Fh)

This command specifies the higher nibble of the 8-bit column start address for the display data RAM under Page Addressing Mode. The column address will be incremented by each data access. Please refer to Section Table 9-1 and Section 10.1.3 for details.

10.1.3 Set Memory Addressing Mode (20h)

There are 3 different memory addressing mode in SSD1306: page addressing mode, horizontal addressing mode and vertical addressing mode. This command sets the way of memory addressing into one of the above three modes. In there, "COL" means the graphic display data RAM column.

Page addressing mode (A[1:0]=10xb)

In page addressing mode, after the display RAM is read/written, the column address pointer is increased automatically by 1. If the column address pointer reaches column end address, the column address pointer is reset to column start address and page address pointer is not changed. Users have to set the new page and column addresses in order to access the next page RAM content. The sequence of movement of the PAGE and column address point for page addressing mode is shown in Figure 10-1.

 COL0
 COL 1

 COL 126
 COL 127

 PAGE0
 →
 →
 →

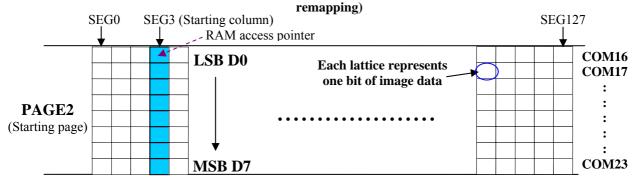
Figure 10-1: Address Pointer Movement of Page addressing mode

In normal display data RAM read or write and page addressing mode, the following steps are required to define the starting RAM access pointer location:

- Set the page start address of the target display location by command B0h to B7h.
- Set the lower start column address of pointer by command 00h~0Fh.
- Set the upper start column address of pointer by command 10h~1Fh.

For example, if the page address is set to B2h, lower column address is 03h and upper column address is 10h, then that means the starting column is SEG3 of PAGE2. The RAM access pointer is located as shown in Figure 10-2. The input data byte will be written into RAM position of column 3.

Figure 10-2 : Example of GDDRAM access pointer setting in Page Addressing Mode (No row and column-



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Horizontal addressing mode (A[1:0]=00b)

In horizontal addressing mode, after the display RAM is read/written, the column address pointer is increased automatically by 1. If the column address pointer reaches column end address, the column address pointer is reset to column start address and page address pointer is increased by 1. The sequence of movement of the page and column address point for horizontal addressing mode is shown in Figure 10-3. When both column and page address pointers reach the end address, the pointers are reset to column start address and page start address (Dotted line in Figure 10-3.)

Figure 10-3: Address Pointer Movement of Horizontal addressing mode

Vertical addressing mode: (A[1:0]=01b)

In vertical addressing mode, after the display RAM is read/written, the page address pointer is increased automatically by 1. If the page address pointer reaches the page end address, the page address pointer is reset to page start address and column address pointer is increased by 1. The sequence of movement of the page and column address point for vertical addressing mode is shown in Figure 10-4. When both column and page address pointers reach the end address, the pointers are reset to column start address and page start address (Dotted line in Figure 10-4.)

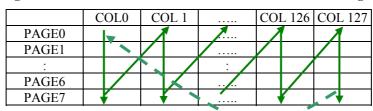


Figure 10-4: Address Pointer Movement of Vertical addressing mode

In normal display data RAM read or write and horizontal / vertical addressing mode, the following steps are required to define the RAM access pointer location:

- Set the column start and end address of the target display location by command 21h.
- Set the page start and end address of the target display location by command 22h.

Example is shown in Figure 10-5.

10.1.4 Set Column Address (21h)

This triple byte command specifies column start address and end address of the display data RAM. This command also sets the column address pointer to column start address. This pointer is used to define the current read/write column address in graphic display data RAM. If horizontal address increment mode is enabled by command 20h, after finishing read/write one column data, it is incremented automatically to the next column address. Whenever the column address pointer finishes accessing the end column address, it is reset back to start column address and the row address is incremented to the next row.

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10.1.5 Set Page Address (22h)

This triple byte command specifies page start address and end address of the display data RAM. This command also sets the page address pointer to page start address. This pointer is used to define the current read/write page address in graphic display data RAM. If vertical address increment mode is enabled by command 20h, after finishing read/write one page data, it is incremented automatically to the next page address. Whenever the page address pointer finishes accessing the end page address, it is reset back to start page address.

The figure below shows the way of column and page address pointer movement through the example: column start address is set to 2 and column end address is set to 125, page start address is set to 1 and page end address is set to 6; Horizontal address increment mode is enabled by command 20h. In this case, the graphic display data RAM column accessible range is from column 2 to column 125 and from page 1 to page 6 only. In addition, the column address pointer is set to 2 and page address pointer is set to 1. After finishing read/write one pixel of data, the column address is increased automatically by 1 to access the next RAM location for next read/write operation (*solid line in Figure 10-5*). Whenever the column address pointer finishes accessing the end column 125, it is reset back to column 2 and page address is automatically increased by 1 (*solid line in Figure 10-5*). While the end page 6 and end column 125 RAM location is accessed, the page address is reset back to 1 and the column address is reset back to 2 (*dotted line in Figure 10-5*).

 Col 0
 Col 1
 Col 2

 Col 125
 Col 126
 Col 127

 PAGE0

Figure 10-5: Example of Column and Row Address Pointer Movement

10.1.6 Set Display Start Line (40h~7Fh)

This command sets the Display Start Line register to determine starting address of display RAM, by selecting a value from 0 to 63. With value equal to 0, RAM row 0 is mapped to COM0. With value equal to 1, RAM row 1 is mapped to COM0 and so on.

Refer to Table 10-1 for more illustrations.

10.1.7 Set Contrast Control for BANK0 (81h)

This command sets the Contrast Setting of the display. The chip has 256 contrast steps from 00h to FFh. The segment output current increases as the contrast step value increases.

10.1.8 Set Segment Re-map (A0h/A1h)

This command changes the mapping between the display data column address and the segment driver. It allows flexibility in OLED module design. Please refer to Table 9-1.

This command only affects subsequent data input. Data already stored in GDDRAM will have no changes.

10.1.9 Entire Display ON (A4h/A5h)

A4h command enable display outputs according to the GDDRAM contents.

If A5h command is issued, then by using A4h command, the display will resume to the GDDRAM contents. In other words, A4h command resumes the display from entire display "ON" stage.

A5h command forces the entire display to be "ON", regardless of the contents of the display data RAM.

10.1.10 Set Normal/Inverse Display (A6h/A7h)

This command sets the display to be either normal or inverse. In normal display a RAM data of 1 indicates an "ON" pixel while in inverse display a RAM data of 0 indicates an "ON" pixel.

10.1.11 Set Multiplex Ratio (A8h)

This command switches the default 63 multiplex mode to any multiplex ratio, ranging from 16 to 63. The output pads COM0~COM63 will be switched to the corresponding COM signal.

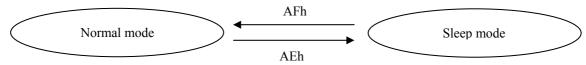
10.1.12 Set Display ON/OFF (AEh/AFh)

These single byte commands are used to turn the OLED panel display ON or OFF.

When the display is ON, the selected circuits by Set Master Configuration command will be turned ON. When the display is OFF, those circuits will be turned OFF and the segment and common output are in V_{SS} state and high impedance state, respectively. These commands set the display to one of the two states:

AEh : Display OFFAFh : Display ON

Figure 10-6: Transition between different modes



10.1.13 Set Page Start Address for Page Addressing Mode (B0h~B7h)

This command positions the page start address from 0 to 7 in GDDRAM under Page Addressing Mode. Please refer to Table 9-1 and Section 10.1.3 for details.

10.1.14 Set COM Output Scan Direction (C0h/C8h)

This command sets the scan direction of the COM output, allowing layout flexibility in the OLED module design. Additionally, the display will show once this command is issued. For example, if this command is sent during normal display then the graphic display will be vertically flipped immediately. Please refer to Table 10-3 for details.

10.1.15 Set Display Offset (D3h)

This is a double byte command. The second command specifies the mapping of the display start line to one of COM0~COM63 (assuming that COM0 is the display start line then the display start line register is equal to 0).

For example, to move the COM16 towards the COM0 direction by 16 lines the 6-bit data in the second byte should be given as 010000b. To move in the opposite direction by 16 lines the 6-bit data should be given by 64 - 16, so the second byte would be 100000b. The following two tables (Table 10-1, Table 10-2) show the example of setting the command C0h/C8h and D3h.

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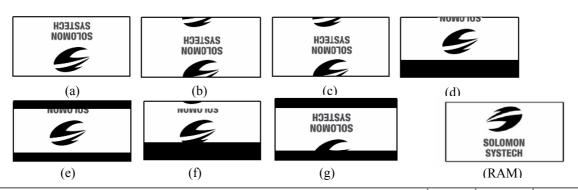
Table 10-1: Example of Set Display Offset and Display Start Line with no Remap

						Out	put						1
		64 rmal		64 mal		i4		56 rmal		56 mal		56 mal	Set MUX ratio(A8h)
Hardware		rmal 0		mal 8		mal O		rmal 0		mal 8		mal 0	COM Normal / Remapped (C0h / C8h) Display offset (D3h)
pin name		0	•	0		3		0		0		8	Display start line (40h - 7Fh)
COM0 COM1	Row0 Row1	RAM0 RAM1	Row8 Row9	RAM8 RAM9	Row0 Row1	RAM8 RAM9	Row0 Row1	RAM0 RAM1	Row8 Row9	RAM8 RAM9	Row0 Row1	RAM8 RAM9	
COM2	Row2	RAM2	Row10	RAM10	Row2	RAM10	Row2	RAM2	Row10	RAM10	Row2	RAM10	
COM3	Row3	RAM3	Row11	RAM11	Row3	RAM11	Row3	RAM3	Row11	RAM11	Row3	RAM11	
COM4 COM5	Row4 Row5	RAM4 RAM5	Row12 Row13	RAM12 RAM13	Row4 Row5	RAM12 RAM13	Row4 Row5	RAM4 RAM5	Row12 Row13	RAM12 RAM13	Row4 Row5	RAM12 RAM13	
COM6	Row6	RAM6	Row14	RAM14	Row6	RAM14	Row6	RAM6	Row14	RAM14	Row6	RAM14	
COM7 COM8	Row7 Row8	RAM7 RAM8	Row15 Row16	RAM15 RAM16	Row7 Row8	RAM15 RAM16	Row7 Row8	RAM7 RAM8	Row15 Row16	RAM15 RAM16	Row7 Row8	RAM15 RAM16	
COM9	Row9	RAM9	Row17	RAM17	Row9	RAM17	Row9	RAM9	Row17	RAM17	Row9	RAM17	
COM10	Row10	RAM10	Row18	RAM18	Row10	RAM18	Row10	RAM10	Row18	RAM18	Row10	RAM18	
COM11 COM12	Row11 Row12	RAM11 RAM12	Row19 Row20	RAM19 RAM20	Row11 Row12	RAM19 RAM20	Row11 Row12	RAM11 RAM12	Row19 Row20	RAM19 RAM20	Row11 Row12	RAM19 RAM20	
COM13	Row13	RAM13	Row21	RAM21	Row13	RAM21	Row13	RAM13	Row21	RAM21	Row13	RAM21	
COM14 COM15	Row14 Row15	RAM14 RAM15	Row22 Row23	RAM22 RAM23	Row14 Row15	RAM22 RAM23	Row14 Row15	RAM14 RAM15	Row22 Row23	RAM22 RAM23	Row14 Row15	RAM22 RAM23	
COM16	Row16	RAM16	Row24	RAM24	Row16	RAM24	Row16	RAM16	Row24	RAM24	Row16	RAM24	
COM17	Row17	RAM17	Row25	RAM25	Row17	RAM25	Row17	RAM17	Row25	RAM25	Row17	RAM25	
COM18 COM19	Row18 Row19	RAM18 RAM19	Row26 Row27	RAM26 RAM27	Row18 Row19	RAM26 RAM27	Row18 Row19	RAM18 RAM19	Row26 Row27	RAM26 RAM27	Row18 Row19	RAM26 RAM27	
COM20	Row20	RAM20	Row28	RAM28	Row20	RAM28	Row20	RAM20	Row28	RAM28	Row20	RAM28	
COM21 COM22	Row21 Row22	RAM21 RAM22	Row29 Row30	RAM29 RAM30	Row21 Row22	RAM29 RAM30	Row21 Row22	RAM21 RAM22	Row29 Row30	RAM29 RAM30	Row21 Row22	RAM29 RAM30	
COM23	Row23	RAM23	Row31	RAM31	Row23	RAM31	Row23	RAM23	Row31	RAM31	Row23	RAM31	
COM24	Row24	RAM24	Row32	RAM32	Row24	RAM32	Row24	RAM24	Row32	RAM32	Row24	RAM32	
COM25 COM26	Row25 Row26	RAM25 RAM26	Row33 Row34	RAM33 RAM34	Row25 Row26	RAM33 RAM34	Row25 Row26	RAM25 RAM26	Row33 Row34	RAM33 RAM34	Row25 Row26	RAM33 RAM34	
COM27	Row27	RAM27	Row35	RAM35	Row27	RAM35	Row27	RAM27	Row35	RAM35	Row27	RAM35	
COM28 COM29	Row28 Row29	RAM28 RAM29	Row36 Row37	RAM36 RAM37	Row28 Row29	RAM36 RAM37	Row28 Row29	RAM28 RAM29	Row36 Row37	RAM36 RAM37	Row28 Row29	RAM36 RAM37	
COM30	Row30	RAM30	Row38	RAM38	Row30	RAM38	Row30	RAM30	Row38	RAM38	Row30	RAM38	
COM31	Row31	RAM31	Row39	RAM39	Row31	RAM39	Row31	RAM31	Row39	RAM39	Row31	RAM39	
COM32 COM33	Row32 Row33	RAM32 RAM33	Row40 Row41	RAM40 RAM41	Row32 Row33	RAM40 RAM41	Row32 Row33	RAM32 RAM33	Row40 Row41	RAM40 RAM41	Row32 Row33	RAM40 RAM41	
COM34	Row34	RAM34	Row42	RAM42	Row34	RAM42	Row34	RAM34	Row42	RAM42	Row34	RAM42	
COM35	Row35	RAM35	Row43	RAM43	Row35	RAM43	Row35	RAM35	Row43	RAM43	Row35	RAM43	
COM36 COM37	Row36 Row37	RAM36 RAM37	Row44 Row45	RAM44 RAM45	Row36 Row37	RAM44 RAM45	Row36 Row37	RAM36 RAM37	Row44 Row45	RAM44 RAM45	Row36 Row37	RAM44 RAM45	
COM38	Row38	RAM38	Row46	RAM46	Row38	RAM46	Row38	RAM38	Row46	RAM46	Row38	RAM46	
COM39 COM40	Row39 Row40	RAM39 RAM40	Row47 Row48	RAM47 RAM48	Row39 Row40	RAM47 RAM48	Row39 Row40	RAM39 RAM40	Row47 Row48	RAM47 RAM48	Row39 Row40	RAM47 RAM48	
COM41	Row41	RAM41	Row49	RAM49	Row41	RAM49	Row41	RAM41	Row49	RAM49	Row41	RAM49	
COM42	Row42	RAM42	Row50	RAM50	Row42	RAM50	Row42	RAM42	Row50	RAM50	Row42	RAM50	
COM43 COM44	Row43 Row44	RAM43 RAM44	Row51 Row52	RAM51 RAM52	Row43 Row44	RAM51 RAM52	Row43 Row44	RAM43 RAM44	Row51 Row52	RAM51 RAM52	Row43 Row44	RAM51 RAM52	
COM45	Row45	RAM45	Row53	RAM53	Row45	RAM53	Row45	RAM45	Row53	RAM53	Row45	RAM53	
COM46 COM47	Row46 Row47	RAM46 RAM47	Row54 Row55	RAM54 RAM55	Row46 Row47	RAM54 RAM55	Row46 Row47	RAM46 RAM47	Row54 Row55	RAM54 RAM55	Row46 Row47	RAM54 RAM55	
COM48	Row48	RAM48	Row56	RAM56	Row48	RAM56	Row48	RAM48	-	-	Row48	RAM56	
COM49	Row49	RAM49	Row57	RAM57	Row49	RAM57	Row49	RAM49	-	-	Row49	RAM57	
COM50 COM51	Row50 Row51	RAM50 RAM51	Row58 Row59	RAM58 RAM59	Row50 Row51	RAM58 RAM59	Row50 Row51	RAM50 RAM51	-	-	Row50 Row51	RAM58 RAM59	
COM52	Row52	RAM52	Row60	RAM60	Row52	RAM60	Row52	RAM52	-	-	Row52	RAM60	
COM53 COM54	Row53 Row54	RAM53 RAM54	Row61 Row62	RAM61 RAM62	Row53 Row54	RAM61 RAM62	Row53 Row54	RAM53 RAM54	-	-	Row53 Row54	RAM61 RAM62	
COM55	Row55	RAM55	Row63	RAM63	Row55	RAM63	Row55	RAM55	-	-	Row55	RAM63	
COM56	Row56	RAM56	Row0	RAM0	Row56	RAM0	-	-	Row0	RAM0	-	-	
COM57 COM58	Row57 Row58	RAM57 RAM58	Row1 Row2	RAM1 RAM2	Row57 Row58	RAM1 RAM2	-	-	Row1 Row2	RAM1 RAM2	-	-	
COM59	Row59	RAM59	Row3	RAM3	Row59	RAM3	-	-	Row3	RAM3	-	-	
COM60 COM61	Row60 Row61	RAM60 RAM61	Row4 Row5	RAM4 RAM5	Row60 Row61	RAM4 RAM5	-	-	Row4 Row5	RAM4 RAM5	-	-	
COM62	Row62	RAM62	Row6	RAM6	Row62	RAM6	-	-	Row6	RAM6	-	-	
COM63	Row63	RAM63	Row7	RAM7	Row63	RAM7	-	-	Row7	RAM7	-	-	
Display examples	(a)	(1	b)	(0	c)	(d)	(e)	((f)	
													•
_				. —									
				П		•					- 11		
	-				6010	MON			SOLO	MUN	- 11		
	90	LOMON				MON rech			SYST		- 11		SOLOMON
		YSTECH			010								CVCTECH
		(a)		, L	(b)			(c	:)			(d)
						•					2	2	
	SC	DLOMON				OMON					SUI	OMON	
	61				SYS	TECH						TECH	
		(e)			(1	f)					(RA	AM)	

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Table 10-2: Example of Set Display Offset and Display Start Line with Remap

						•	Output								1
		64		54		34		18		18		8		18	Set MUX ratio(A8h)
Hardware		map 0		map 8		map 0		map 0		map 8		map O		map B	COM Normal / Remapped (C0h / C8h) Display offset (D3h)
pin name		0		0		8		0		0		8		6	Display start line (40h - 7Fh)
COMO	Row63	RAM63	Row7	RAM7	Row63	RAM7	Row47	RAM47	-	-	Row47	RAM55	-	-	
COM1 COM2	Row62 Row61	RAM62 RAM61	Row6 Row5	RAM6 RAM5	Row62 Row61	RAM6 RAM5	Row46 Row45	RAM46 RAM45	-	-	Row46 Row45	RAM54 RAM53	-	-	
COM3	Row60	RAM60	Row4	RAM4	Row60	RAM4	Row44	RAM44	-	-	Row44	RAM52	-	-	ľ
COM4	Row59	RAM59	Row3	RAM3	Row59	RAM3	Row43	RAM43	-	-	Row43	RAM51	-	-	
COM5 COM6	Row58 Row57	RAM58 RAM57	Row2 Row1	RAM2 RAM1	Row58 Row57	KAM2 KAM1	Row42 Row41	RAM42 RAM41	-	-	Row42 Row41	KAM50 KAM49	-	-	
COM7	Row56	RAM56	Row0	RAM0	Row56	RAMO	Row40	RAM40	-	-	Row40	RAM48	-	-	
COIMB	Row55	RAM55	Row63	RAM63	Row55	KAM63	Row39	RAM39	Row47	KAM47	Row39	RAM47	Row47	KAM63	j
COM10	Row54 Row53	RAM53	Row62 Row61	RAM62 RAM61	Row54 Row53	RAM62 RAM61	Row38 Row37	RAM37	Row46 Row45	RAM46 RAM45	Row38 Row37	RAM46 RAM45	Row46 Row45	RAM62 RAM61	!
COM11	Row52	RAM52	Row60	RAM60	Row52	RAM60	Row36	RAM36	Row43	RAM44	Row36	RAM44	Row43	RAM60	
COM12	Row51	RAM51	Row59	KAM59	Row51	KAM59	Row35	KAN35	Row43	KAM43	Row35	KAM43	Row43	KAM59	ĺ
COM13	Row50	RAM50	Row58	RAM58	Row50	RAM58	Row34	RAM34	Row42	RAM42	Row34	RAM42	Row42	RAM58	
COM14 COM15	Row49 Row48	RAM49 KAM48	Row57 Row56	RAM57 RAM56	Row49 Row48	RAM57 RAM56	Row33 Row32	RAM33 RAM32	Row41 Row40	RAM41 KAM40	Row33 Row32	RAM41 KAM40	Row41 Row40	RAM57 KAM56	
COM16	Row47	RAM47	Row55	RAM55	Row47	RAM55	Row31	RAM31	Row39	RAM39	Row31	RAM39	Row39	RAM55	ľ
COM17	Row46	RAM46	Row54	RAM54	Row46	RAM54	Row30	RAM30	Row38	RAM38	Row30	RAM38	Row38	RAM54	
COM18	Row45 Row44	RAM45 RAM44	Row53 Row52	RAM53 RAM52	Row45 Row44	RAM53 RAM52	Row29 Row28	RAM29 RAM28	Row37 Row36	RAM36	Row29 Row28	RAM37	Row37 Row36	RAM53 RAM52	
COM20	Row43	RAM43	Row51	RAM51	Row43	RAM51	Row27	RAM27	Row35	RAM35	Row27	RAM35	Row35	RAM51	
COM21	Row42	KAM42	Row50	RAM50	Row42	RAM50	Row26	RAM26	Row34	KAN34	Row26	RAM34	Row34	RAM50	j
COM22	Row41	RAM41	Row49	RAM49	Row41	RAM49	Row25	RAM25 RAM24	Row33	RAM33 RAM32	Row25	RAM33 RAM32	Row33	RAM49	
COM23 COM24	Row40 Row39	RAM40 KAM39	Row48 Row47	RAM48 RAM47	Row40 Row39	RAM48 KAM47	Row24 Row23	KAM23	Row32 Row31	RAIVI32 RAIVI31	Row24 Row23	KAIVI32 KAIVI31	Row32 Row31	RAM48 KAM47	
COM25	Row38	RAM38	Row46	RAM46	Row38	RAM46	Row22	RAM22	Row30	RAM30	Row22	RAM30	Row30	RAM46	ľ
COM26	Row37	RAM37	Row45	RAM45	Row37	RAM45	Row21	RAM21	Row29	RAM29	Row21	RAM29	Row29	RAM45	
COM27 COM28	Row36 Row35	RAM35	Row43	RAM43	Row36 Row35	RAM43	Row20 Row19	RAM20 RAM19	Row28 Row27	RAM28 RAM27	Row20 Row19	RAM28 RAM27	Row28 Row27	RAM43	
COM29	Row34	RAM34	Row42	RAM42	Row34	RAM42	Row18	RAM18	Row26	RAM26	Row18	RAM26	Row26	RAM42	
COMBO	Row33	RAM33	Row41	KAM41	Row33	KAM41	Row17	RAM17	Row25	KAM25	Row17	KAM25	Row25	KAM41	j
COM31 COM32	Row32 Row31	RAM32 RAM31	Row40 Row39	RAM40 RAM39	Row32 Row31	RAM40 RAM39	Row16 Row15	RAM16 RAM15	Row24 Row23	RAM24 RAM23	Row16 Row15	RAM24 RAM23	Row24 Row23	RAM40 RAM39	
COIVISZ	Row30	RAM30	Row38	KAN38	Row30	KAN38	Row13	RAM14	Row23	KANZ2	Row13 Row14	KAM22	Row23	RAN38	
COM34	Row29	RAM29	Row37	RAM37	Row29	RAM37	Row13	RAM13	Row21	RAM21	Row13	RAM21	Row21	RAM37	ľ
COM35	Row28	RAM28	Row36	RAM36	Row28	RAM36	Row12	RAM12	Row20	RAM20	Row12	RAM20	Row20	RAM36	
COM36 COM37	Row27 Row26	RAM26	Row35 Row34	RAM35 RAM34	Row27 Row26	RAM35 RAM34	Row11 Row10	RAM11 RAM10	Row19 Row18	RAM19 RAM18	Row10	RAM19 RAM18	Row19 Row18	RAM35 RAM34	
COM38	Row25	RAM25	Row33	RAM33	Row25	RAM33	Row9	RAM9	Row17	RAM17	Row9	RAM17	Row17	RAM33	
COM39	Row24	KAM24	Row32	KAN32	Row24	KAN32	Row8	KAMB	Row16	KAM16	Row8	RAM16	Row16	KAN32	j
COM40 COM41	Row23 Row22	RAM23 RAM22	Row31 Row30	RAM31 RAM30	Row23 Row22	RAM31 RAM30	Row7 Row6	RAM7 RAM6	Row15 Row14	RAM15 RAM14	Row7 Row6	RAM15 RAM14	Row15 Row14	RAM31 RAM30	
COM42	Row21	RAM21	Row29	RAM29	Row21	RAM29	Row5	RAM5	Row13	RAM13	Row5	RAM13	Row13	RAM29	
COM43	Row20	RAM20	Row28	RAM28	Row20	RAM28	Row4	RAM4	Row12	RAM12	Row4	RAM12	Row12	RAM28	ĺ
COM44	Row19	RAM19	Row27	RAM27	Row19	RAM27	Row3	RAM3	Row11	RAM11	Row3	RAM11	Row11	RAM27	ļ
COM45 COM46	Row18 Row17	RAM18 RAM17	Row26 Row25	RAM26 RAM25	Row18 Row17	RAM26 RAM25	Row2 Row1	Kamz Rami	Row10 Row9	RAM10 RAM9	Row2 Row1	RAM10 RAM9	Row10 Row9	RAM26 RAM25	
COM47	Row16	RAM16	Row24	RAM24	Row16	RAM24	Row0	RAMO	Row8	RAM8	Row0	RAM8	Row8	RAM24	ľ
COM48	Row15	RAM15	Row23	RAM23	Row15	KAM23	-	-	Row/	KAM7	-	-	Row/	RAM23	
COM49 COM50	Row14 Row13	RAM14 RAM13	Row22 Row21	RAM22 RAM21	Row14 Row13	RAM22 RAM21	-	-	Row6 Row5	RAM6 RAM5	-	-	Row6 Row5	RAM22 RAM21	
COIVI50	Row12	RAM12	Row20	RAM20	Row12	RAM20	-	-	Row4	KAM4	-	-	Row4	RAM20	
COM52	Row11	RAM11	Row19	RAM19	Row11	RAM19	-	-	Row3	RAM3	-	-	Row3	RAM19	j
COM53	Row10	RAM10	Row18	RAM18	Row10	RAM18	-	-	Row2	RAM2	-	-	Row2	RAM18 KAM17	Į.
COM54 COM55	Row8	KAM9 KAM8	Row17 Row16	RAM17 RAM16	Rows	KAM17 KAM16		-	Row1	RAM1 RAMU		-	Row1 Row0	RAM16	1
COM56	Row7	RAM7	Row15	RAM15	Row7	RAM15	-	-	-	-	-	-	-	-	ſ
COM57	Row6	RAM6	Row14	RAM14	Row6	RAM14	-	-	-	-	-	-	-	-	1
COM59	Row5 Row4	RAM5 RAM4	Row13 Row12	RAM13 RAM12	Row5 Row4	RAM13 RAM12		-	_	-	_	-	-	-	l
COM60	Row3	RAM3	Row11	RAM11	Row3	RAM11	-	-	-	-	-	-	-	-	ſ
COM61	Row2	KAM2	Row10	RAM10	Row2	RAM10	-	-	-	-	-	-	-	-	j .
COM62 COM63	Row1 Row0	RAM1 RAM0	Row9 Row8	RAM9 RAM8	Row1 Row0	RAM9 RAM8	-	-	-	-	-	-	-	-	
Display							-								{
examples	((a)	(b)	(c)	(d)	(e)	(f)	()	g)	
F	•						•		•		•				•



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10.1.16 Set Display Clock Divide Ratio/ Oscillator Frequency (D5h)

This command consists of two functions:

- Display Clock Divide Ratio (D)(A[3:0])
 Set the divide ratio to generate DCLK (Display Clock) from CLK. The divide ratio is from 1 to 16, with reset value = 1. Please refer to section 8.3 for the details relationship of DCLK and CLK.
- Oscillator Frequency (A[7:4])
 Program the oscillator frequency Fosc that is the source of CLK if CLS pin is pulled high. The 4-bit value results in 16 different frequency settings available as shown below. The default setting is 1000b.

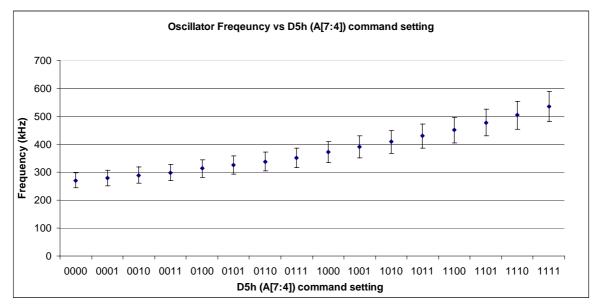


Figure 10-7: Oscillator frequency setting

10.1.17 Set Pre-charge Period (D9h)

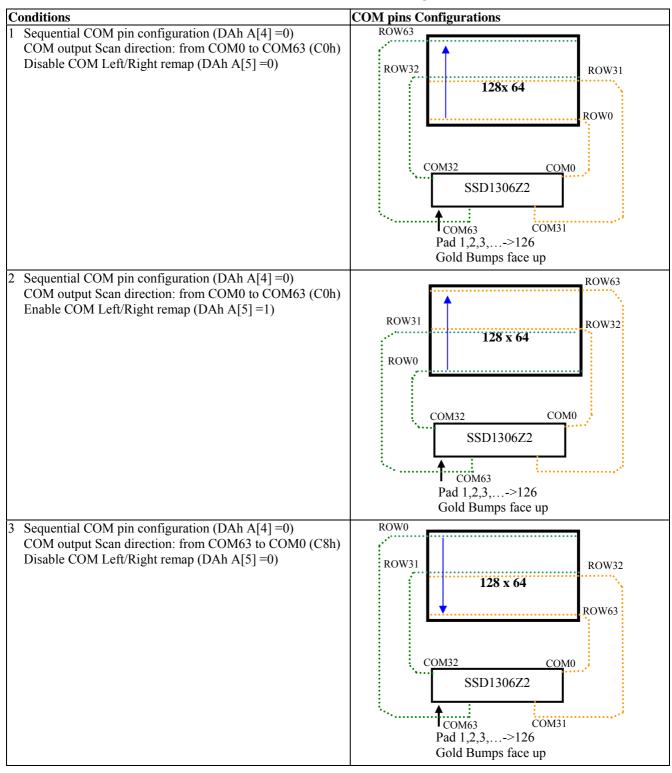
This command is used to set the duration of the pre-charge period. The interval is counted in number of DCLK, where RESET equals 2 DCLKs.

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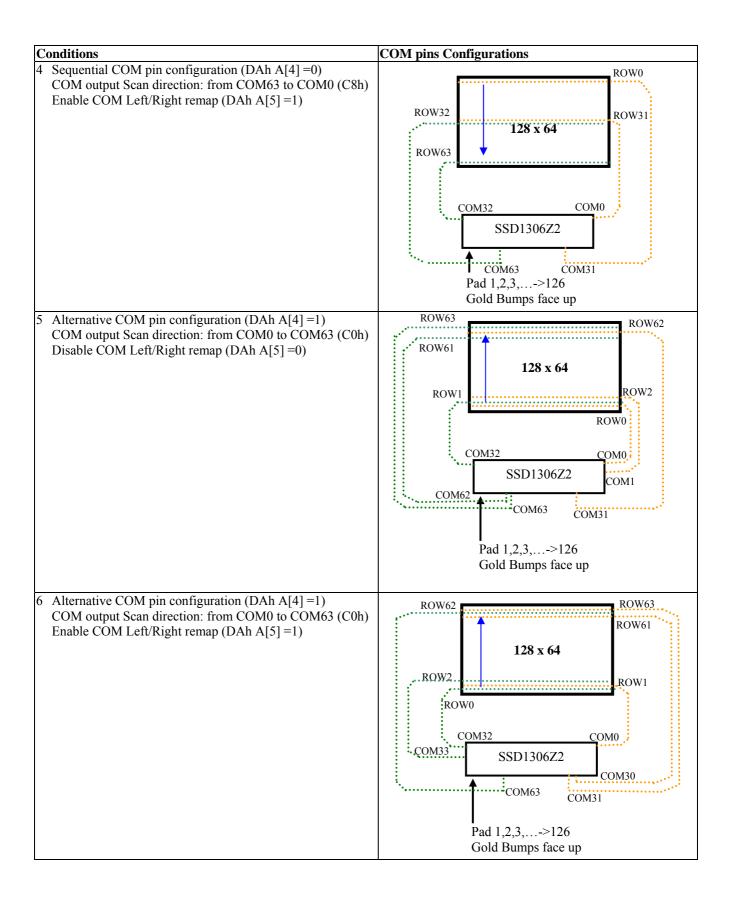
10.1.18 Set COM Pins Hardware Configuration (DAh)

This command sets the COM signals pin configuration to match the OLED panel hardware layout. The table below shows the COM pin configuration under different conditions (for MUX ratio =64):

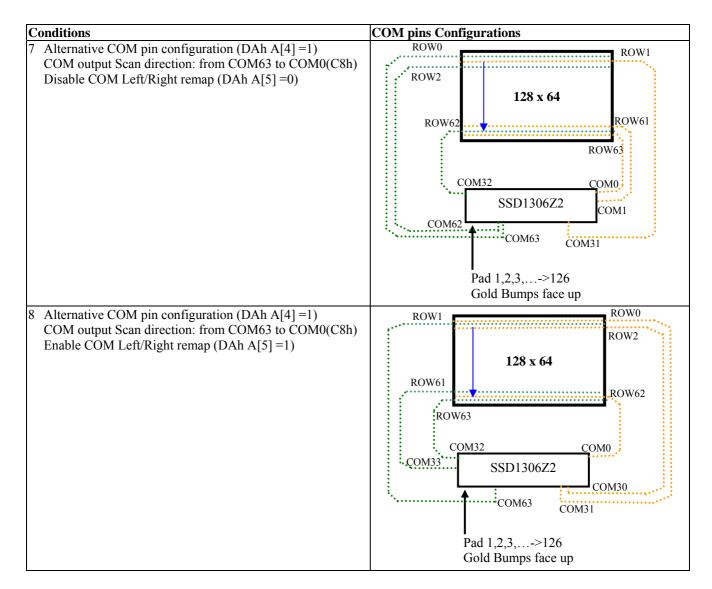
Table 10-3: COM Pins Hardware Configuration



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10.1.19 Set V_{COMH} Deselect Level (DBh)

This command adjusts the V_{COMH} regulator output.

10.1.20 NOP (E3h)

No Operation Command

10.1.21 Status register Read

This command is issued by setting D/C# ON LOW during a data read (See Figure 13-1 to Figure 13-2 for parallel interface waveform). It allows the MCU to monitor the internal status of the chip. No status read is provided for serial mode.

10.1.22 Charge Pump Setting (8Dh)

This command controls the ON/OFF of the Charge Pump. The Charge Pump must be enabled by the following command sequence:

8Dh; Charge Pump Setting 14h; Enable Charge Pump

AFh; Display ON

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10.2 Graphic Acceleration Command

10.2.1 Horizontal Scroll Setup (26h/27h)

This command consists of consecutive bytes to set up the horizontal scroll parameters and determines the scrolling start page, end page and scrolling speed.

Before issuing this command the horizontal scroll must be deactivated (2Eh). Otherwise, RAM content may be corrupted.

The SSD1306 horizontal scroll is designed for 128 columns scrolling. The following two figures (Figure 10-8, Figure 10-9, Figure 10-10) show the examples of using the horizontal scroll:

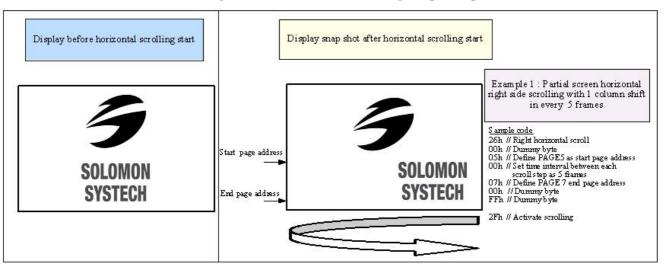
SEG0 SEG3 SEG126 SEG124 SEG125 SEG127 SEG1 SEG123 SEG1. Original Setting SEG127 SEG122 SEG126 123 After one scroll SEG121 step

Figure 10-8: Horizontal scroll example: Scroll RIGHT by 1 column

Figure 10-9: Horizontal scroll example: Scroll LEFT by 1 column

Original Setting	SEG0	SEG1	SEG2	SEG3	SEG4	SEG5	:	 :	SEG122	SEG123	SEG124	SEG125	SEG126	SEG127
After one scroll step	SEG1	SEG2	SEG3	SEG4	SEG5	SEG6	:	 ::	SEG123	SEG124	SEG125	SEG126	SEG127	SEG0

Figure 10-10: Horizontal scrolling setup example



10.2.2 Continuous Vertical and Horizontal Scroll Setup (29h/2Ah)

This command consists of 6 consecutive bytes to set up the continuous vertical scroll parameters and determines the scrolling start page, end page, scrolling speed and vertical scrolling offset.

The bytes B[2:0], C[2:0] and D[2:0] of command 29h/2Ah are for the setting of the continuous horizontal scrolling. The byte E[5:0] is for the setting of the continuous vertical scrolling offset. All these bytes together are for the setting of continuous diagonal (horizontal + vertical) scrolling. If the vertical scrolling offset byte E[5:0] is set to zero, then only horizontal scrolling is performed (like command 26/27h).

Before issuing this command the scroll must be deactivated (2Eh). Otherwise, RAM content may be corrupted. The following figure (Figure 10-11) show the example of using the continuous vertical and horizontal scroll:

Example 1 : Full screen diagonal Display before scrolling start Display snap shot after scrolling start scrolling (horizontal right side scrolling with 1 column shift plus Start page address/ vertical scrolling with 1 row up) in No. of rows in top fixed every 6 frames. area =0 (POR) Sample code 29h // Vertical and right horizontal scroll No. of rows in scroll 00h // Dummybyte 00h // Define PAGE0 as start page address azea =64 (POR) 00h #Set time interval between each scroll step as 6 frames
07h // Define PAGE7 as end page address
01h // Set vertical scrolling offset as 1 row SYSTECH End page address 2Fh // Activate scrolling

Figure 10-11: Continuous Vertical and Horizontal scrolling setup example

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10.2.3 Deactivate Scroll (2Eh)

This command stops the motion of scrolling. After sending 2Eh command to deactivate the scrolling action, the ram data needs to be rewritten.

10.2.4 Activate Scroll (2Fh)

This command starts the motion of scrolling and should only be issued after the scroll setup parameters have been defined by the scrolling setup commands :26h/27h/29h/2Ah. The setting in the last scrolling setup command overwrites the setting in the previous scrolling setup commands.

The following actions are prohibited after the scrolling is activated

- 1. RAM access (Data write or read)
- 2. Changing the horizontal scroll setup parameters

10.2.5 Set Vertical Scroll Area(A3h)

This command consists of 3 consecutive bytes to set up the vertical scroll area. For the continuous vertical scroll function (command 29/2Ah), the number of rows that in vertical scrolling can be set smaller or equal to the MUX ratio.

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10.3 Advance Graphic Command

10.3.1 Set Fade Out and Blinking (23h)

This command allow to set the fade mode and adjust the time interval for each fade step. Below figures show the example of Fade Out mode and Blinking mode.

Figure 10-12: Example of Fade Out mode

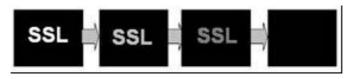


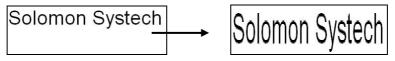
Figure 10-13: Example of Blinking mode



10.3.2 Set Zoom In (D6h)

Under Zoom in mode, one row of display contents is expanded into two rows on the display. That is, contents of $row0\sim31$ fill the whole display panel of 64 rows. It should be notice that the panel must be in alternative COM pin configuration (command DAh A[4] =1) for zoom in function.

Figure 10-14: Example of Zoom In



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11 MAXIMUM RATINGS

Table 11-1: Maximum Ratings (Voltage Referenced to VSS)

Symbol	Parameter	Value	Unit
V_{DD}		-0.3 to +4	V
V_{BAT}	Supply Voltage	-0.3 to +5	V
V_{CC}		0 to 16	V
V_{SEG}	SEG output voltage	0 to V _{CC}	V
V_{COM}	COM output voltage	0 to 0.9*V _{CC}	V
V_{in}	Input voltage	V_{SS} -0.3 to V_{DD} +0.3	V
T_{A}	Operating Temperature	-40 to +85	°C
T_{stg}	Storage Temperature Range	-65 to +150	°C

Maximum ratings are those values beyond which damages to the device may occur. Functional operation should be restricted to the limits in the Electrical Characteristics tables or Pin Description section

This device may be light sensitive. Caution should be taken to avoid exposure of this device to any light source during normal operation. This device is not radiation protected.

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12 DC CHARACTERISTICS

Condition (Unless otherwise specified):

Voltage referenced to V_{SS} $V_{DD} = 1.65$ to 3.3V $T_A = 25$ °C

Table 12-1: DC Characteristics

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V_{CC}	Operating Voltage	-	7	-	15	V
V_{DD}	Logic Supply Voltage	-	1.65	-	3.3	V
V_{BAT}	Charge Pump Regulator Supply Voltage	-	3.3	-	4.2	V
Charge Pump V _{CC}	Charge Pump Output Voltage	$V_{BAT} = 3.3V \sim 4.2V$, Output loading = 6mA	7	7.5	-	V
V_{OH}	High Logic Output Level	$I_{OUT} = 100uA, 3.3MHz$	$0.9 \times V_{DD}$	-	-	V
V_{OL}	Low Logic Output Level	$I_{OUT} = 100uA, 3.3MHz$	-	-	$0.1 \times V_{DD}$	V
V_{IH}	High Logic Input Level	-	$0.8 \times V_{DD}$	-	-	V
V_{IL}	Low Logic Input Level	-	-	-	$0.2 \times V_{DD}$	V
I _{CC, SLEEP}	I _{CC,} Sleep mode Current	V_{DD} = 1.65V~3.3V, V_{CC} = 7V~15V Display OFF, No panel attached	-	-	10	uA
I _{DD, SLEEP}	I _{DD,} Sleep mode Current	$V_{DD} = 1.65 \text{V} \sim 3.3 \text{V}, V_{CC} = 7 \text{V} \sim 15 \text{V}$ Display OFF, No panel attached	-	-	10	uA
I_{CC}	V_{CC} Supply Current $V_{DD} = 2.8V$, $V_{CC} = 12V$, $I_{REF} = 12.5uA$ No loading, Display ON, All ON V_{DD} Supply Current	Contrast = FFh	-	430	780	uA
I_{DD}	$V_{DD} = 2.8V$, $V_{CC} = 12V$, $I_{REF} = 12.5uA$ No loading, Display ON, All ON		-	50	150	uA
	Segment Output Current	Contrast=FFh	-	100	-	
I_{SEG}	V _{DD} =2.8V, V _{CC} =12V,	Contrast=AFh	-	69	-	uA
	I _{REF} =12.5uA, Display ON.	Contrast=3Fh	-	25	-	
Dev	Segment output current uniformity	$\begin{aligned} & \text{Dev} = (I_{\text{SEG}} - I_{\text{MID}}) / I_{\text{MID}} \\ & I_{\text{MID}} = (I_{\text{MAX}} + I_{\text{MIN}}) / 2 \\ & I_{\text{SEG}}[0:131] = \text{Segment current at} \\ & \text{contrast} = \text{FFh} \end{aligned}$	-3	-	+3	%
Adj. Dev	Adjacent pin output current uniformity (contrast = FF)	Adj Dev = $(I[n]-I[n+1]) / (I[n]+I[n+1])$	-2	-	+2	%

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13 AC CHARACTERISTICS

Conditions:

Voltage referenced to V_{SS} V_{DD} =1.65 to3.3V T_A = 25°C

Table 13-1: AC Characteristics

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
Fosc (1)	Oscillation Frequency of Display Timing Generator	$V_{DD} = 2.8V$	333	370	407	kHz
FFRM	Frame Frequency for 64 MUX Mode	128x64 Graphic Display Mode, Display ON, Internal Oscillator Enabled	-	F _{OSC} x 1/(DxKx64)	-	Hz
RES#	Reset low pulse width		3	-	_	us

Note

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 $^{^{(1)}}$ Fosc stands for the frequency value of the internal oscillator and the value is measured when command D5h A[7:4] is in default value.

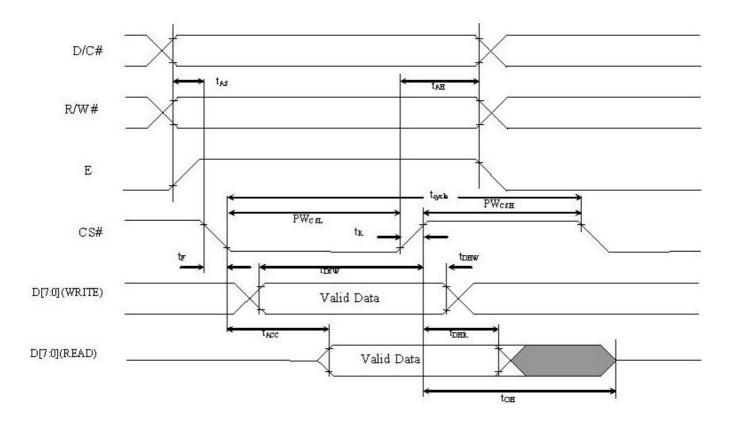
 ⁽²⁾ D: divide ratio (default value = 1)
 K: number of display clocks (default value = 54)
 Please refer to Table 9-1 (Set Display Clock Divide Ratio/Oscillator Frequency, D5h) for detailed description

 ${\bf Table~13-2:6800-Series~MCU~Parallel~Interface~Timing~Characteristics}$

 $(V_{DD} - V_{SS} = 1.65V \text{ to } 3.3V, T_A = 25^{\circ}C)$

Symbol	Parameter	Min	Тур	Max	Unit
t_{cycle}	Clock Cycle Time	300	-	-	ns
t_{AS}	Address Setup Time	5	-	-	ns
t _{AH}	Address Hold Time	0	-	-	ns
t_{DSW}	Write Data Setup Time	40	-	_	ns
$t_{ m DHW}$	Write Data Hold Time	7	-	-	ns
$t_{ m DHR}$	Read Data Hold Time	20	-	-	ns
t_{OH}	Output Disable Time	-	-	70	ns
t _{ACC}	Access Time	-	-	140	ns
PW_{CSL}	Chip Select Low Pulse Width (read) Chip Select Low Pulse Width (write)	120 60	-	-	ns
PW_{CSH}	Chip Select High Pulse Width (read) Chip Select High Pulse Width (write)	60 60	-	-	ns
t_R	Rise Time	-	-	40	ns
$t_{\rm F}$	Fall Time	-	-	40	ns

Figure 13-1: 6800-series MCU parallel interface characteristics



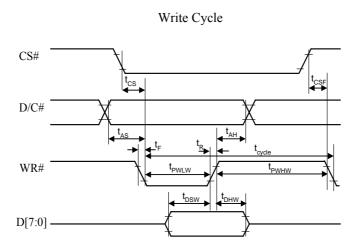
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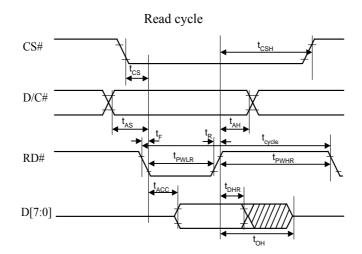
Table 13-3: 8080-Series MCU Parallel Interface Timing Characteristics

 $(V_{DD} - V_{SS} = 1.65V \text{ to } 3.3V, T_A = 25^{\circ}C)$

Symbol	Parameter	Min	Тур	Max	Unit
t _{cycle}	Clock Cycle Time	300	-	-	ns
t_{AS}	Address Setup Time	10	-	-	ns
t_{AH}	Address Hold Time	0	-	-	ns
$t_{ m DSW}$	Write Data Setup Time	40	-	-	ns
$t_{ m DHW}$	Write Data Hold Time	7	-	-	ns
t_{DHR}	Read Data Hold Time	20	-	-	ns
t_{OH}	Output Disable Time	-	-	70	ns
t_{ACC}	Access Time	-	-	140	ns
t_{PWLR}	Read Low Time	120	-	-	ns
t_{PWLW}	Write Low Time	60	-	-	ns
t_{PWHR}	Read High Time	60	-	-	ns
t_{PWHW}	Write High Time	60	-	-	ns
t_{R}	Rise Time	-	-	40	ns
$t_{\rm F}$	Fall Time	-	-	40	ns
t_{CS}	Chip select setup time	0	-	-	ns
t_{CSH}	Chip select hold time to read signal	0	-	-	ns
t _{CSF}	Chip select hold time	20	-	_	ns

Figure 13-2: 8080-series parallel interface characteristics





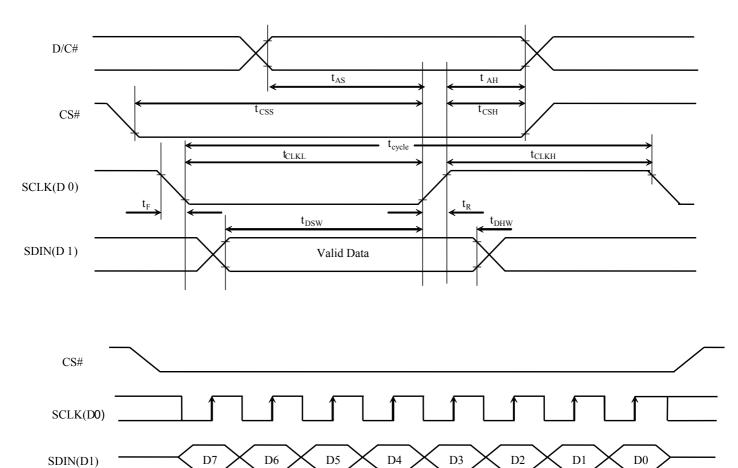
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Table 13-4 : 4-wire Serial Interface Timing Characteristics

 $(V_{DD} - V_{SS} = 1.65 \text{V to } 3.3 \text{V}, T_A = 25 ^{\circ}\text{C})$

Symbol	Parameter	Min	Тур	Max	Unit
$t_{ m cycle}$	Clock Cycle Time	100	-	-	ns
t_{AS}	Address Setup Time	15	-	-	ns
t_{AH}	Address Hold Time	15	-	-	ns
t_{CSS}	Chip Select Setup Time	20	-	-	ns
t_{CSH}	Chip Select Hold Time	10	-	-	ns
$t_{ m DSW}$	Write Data Setup Time	15	-	-	ns
$t_{ m DHW}$	Write Data Hold Time	15	-	-	ns
t_{CLKL}	Clock Low Time	20	-	-	ns
t_{CLKH}	Clock High Time	20	-	-	ns
t_{R}	Rise Time	_	-	40	ns
t_{F}	Fall Time	-	-	40	ns

Figure 13-3: 4-wire Serial interface characteristics



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Table 13-5: 3-wire Serial Interface Timing Characteristics

 $(V_{DD} - V_{SS} = 1.65V \text{ to } 3.3V, T_A = 25^{\circ}C)$

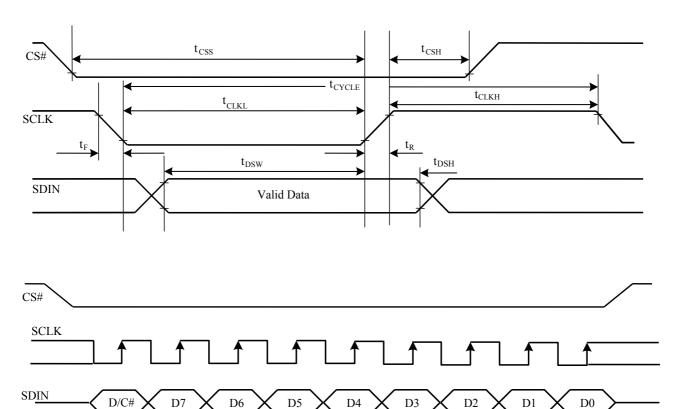
D7

D6

D5

Symbol	Parameter	Min	Тур	Max	Unit
$t_{ m cycle}$	Clock Cycle Time	100	-	-	ns
t_{CSS}	Chip Select Setup Time	20	-	-	ns
t_{CSH}	Chip Select Hold Time	10	-	-	ns
$t_{ m DSW}$	Write Data Setup Time	15	-	-	ns
$t_{ m DHW}$	Write Data Hold Time	15	-	-	ns
$t_{ m CLKL}$	Clock Low Time	20	-	-	ns
t_{CLKH}	Clock High Time	20	-	-	ns
t_R	Rise Time	-	-	40	ns
t_{F}	Fall Time	-	-	40	ns

Figure 13-4: 3-wire Serial interface characteristics



D4

D0

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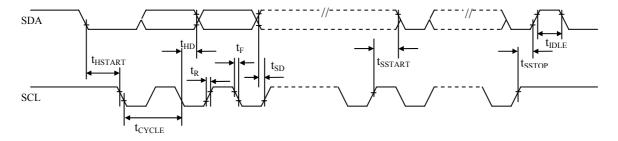
Conditions:

$$V_{\rm DD}$$
 - $V_{\rm SS}$ = $V_{\rm DD}$ - $V_{\rm SS}$ = 1.65V to 3.3V $T_{\rm A}$ = 25°C

Table 13-6: I²C Interface Timing Characteristics

Symbol	Parameter	Min	Тур	Max	Unit
t _{cycle}	Clock Cycle Time	2.5	-	-	us
t _{HSTART}	Start condition Hold Time	0.6	-	-	us
$t_{ m HD}$	Data Hold Time (for "SDA _{OUT} " pin)	0	-	-	ns
	Data Hold Time (for "SDA _{IN} " pin)	300	-	-	ns
t_{SD}	Data Setup Time	100	-	-	ns
t _{SSTART}	Start condition Setup Time (Only relevant for a repeated Start condition)	0.6	-	-	us
t_{SSTOP}	Stop condition Setup Time	0.6	-	-	us
t _R	Rise Time for data and clock pin	-	-	300	ns
$t_{\rm F}$	Fall Time for data and clock pin	-	-	300	ns
t _{IDLE}	Idle Time before a new transmission can start	1.3	-	-	us

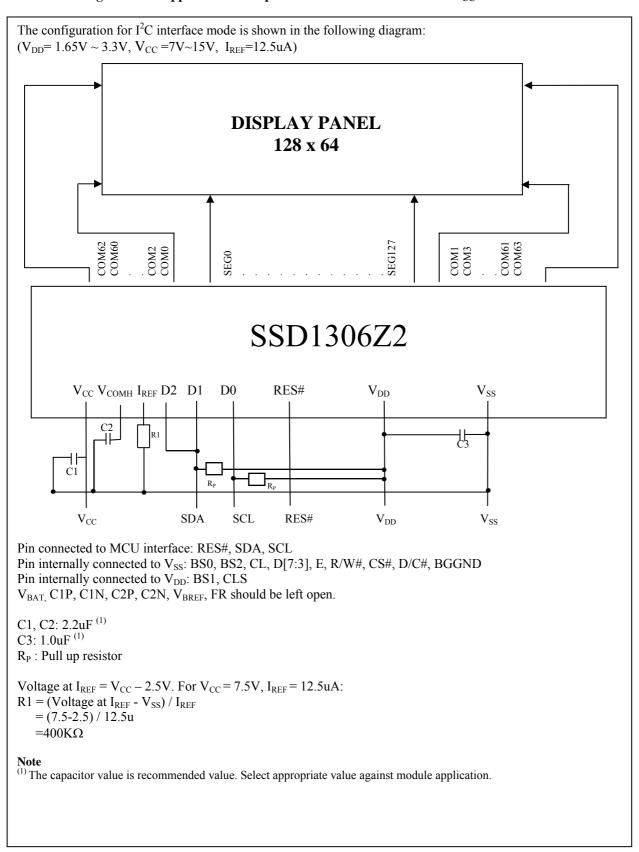
Figure 13-5: I²C interface Timing characteristics



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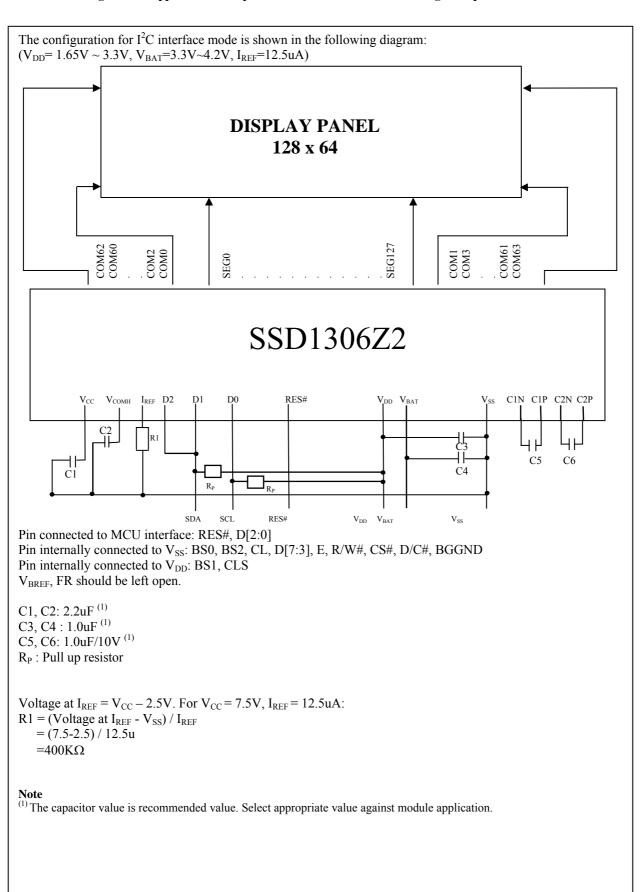
14 Application Example

Figure 14-1: Application Example of SSD1306Z2 with External V_{CC} and I²C interface



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Figure 14-2 Application Example of SSD1306Z2 with Internal Charge Pump and I²C interface



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15 PACKAGE INFORMATION

15.1 SSD1306TR1 Detail Dimension

Figure 15-1 SSD1306TR1 Detail Dimension



Specification:

1. GENERAL TOLERANCE: ±0.05 mm

2.MATERIAL

PI: 75 ± 8 um CU: 15 ± 3 um

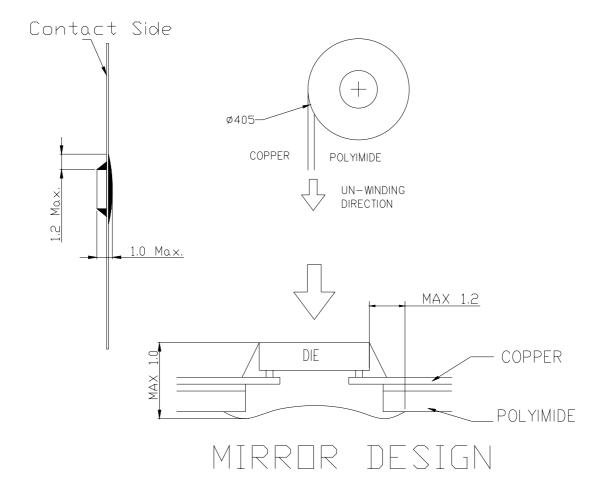
ADHESIVE: 12 ± 3um

SR: 26 ± 14 um

TOLERANCE ± 0.200 mm

FLEX COATING: Min10 um 3.Plating: Sn 0.20 ±0.05 um 4. TAPESITE: 4 SPH,19 mm

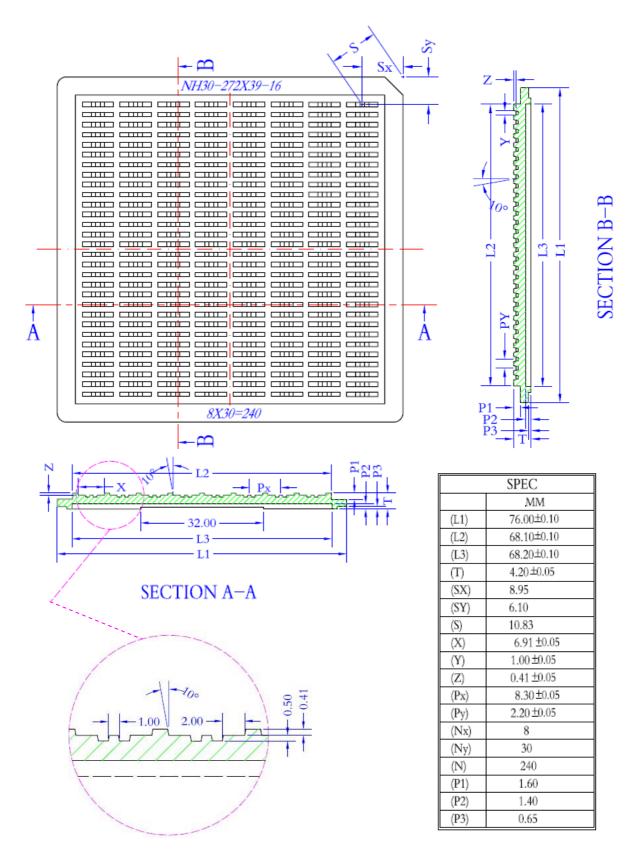
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15.2 SSD1306Z2 Die Tray Information

Figure 15-2: SSD1306Z2 die tray information



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